2.7V to 5.5V Input, 3A Integrated MOSFET Single Synchronous Buck DC/DC Converter

BD9A302QWZ

General Description

BD9A302QWZ is a synchronous buck DC/DC converter with built-in low on-resistance power MOSFETs. This IC is capable of providing current up to 3A. The SLLM™ control provides excellent efficiency characteristics in light-load conditions which make the product ideal for equipment and devices that demand minimal standby power consumption. The oscillating frequency is high at 1MHz using a small value of inductor. BD9A302QWZ is a current mode control DC/DC converter and features high-speed transient response. Phase compensation can also be set easily.

Features

- Single Synchronous Buck DC/DC Converter
- SLLM™ (Simple Light Load Mode) Control
- Over Current Protection
- Short Circuit Protection
- Thermal Shutdown Protection
- Under Voltage Lockout Protection
- UMMP008AZ020 Package
  (Backside Heat Dissipation)
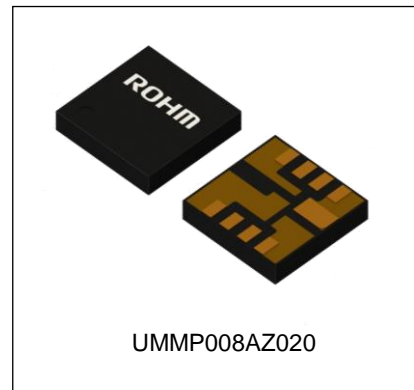
Applications

- Step-Down Power Supply for DSPs, FPGAs, Microprocessors, etc.
- Laptop PCs / Tablet PCs / Servers
- LCD TVs
- Storage Devices (HDDs/SSDs)
- Printers, OA Equipment
- Distributed Power Supplies, Secondary Power Supplies

Key Specifications

- Input Voltage Range: 2.7V to 5.5V
- Output Voltage Range: 0.8V to V_{IN} x 0.7V
- Output Current: 3A(Max)
- Switching Frequency: 1MHz(Typ)
- High-Side MOSFET ON-Resistance: 50mΩ (Typ)
- Low-Side MOSFET ON-Resistance: 50mΩ (Typ)
- Standby Current: 0µA (Typ)

Package

	W (Typ) x D (Typ) x H (Max)
UMMP008AZ020	2.00mm x 2.00mm x 0.40mm

UMMP008AZ020

Typical Application Circuit
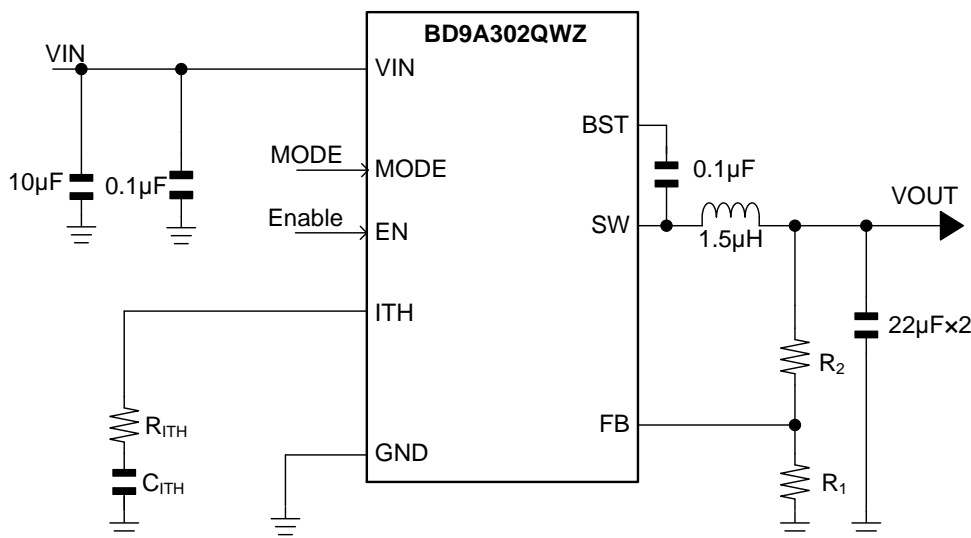
Figure 1. Application Circuit

○Product structure : Silicon monolithic integrated circuit   ○This product has no designed protection against radioactive rays

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Pin Configuration

(TOP VIEW)

```
        ┌─────────────────────────────────┐
        │                                 │
  VIN  ─┤  1        ┌──────┐       8   ├─  GND
        │           │ E-PAD │           │
  EN   ─┤  2        │      │       7   ├─  FB
        │           └──────┘           │
  BST  ─┤  3                   6   ├─  ITH
        │                             │
  SW   ─┤  4                   5   ├─  MODE
        │                                 │
        └─────────────────────────────────┘
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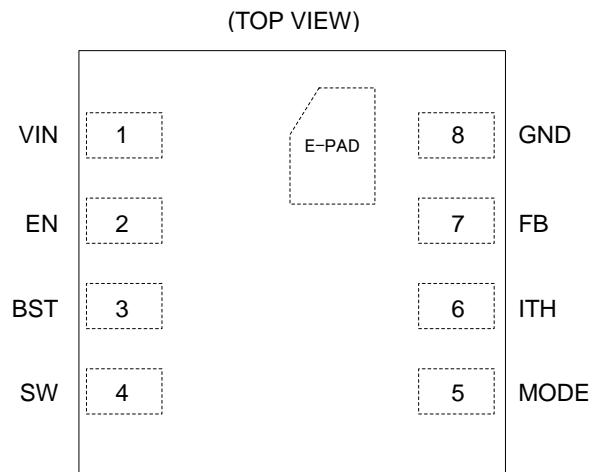
Figure 2. Pin Configuration

Pin Descriptions

Pin No.	Pin Name	Function
1	VIN	Power supply terminal for the switching regulator and control circuit. Connecting 10µF and 0.1µF ceramic capacitors are recommended.
2	EN	Enable terminal. Turning this terminal signal Low (0.8V or lower) forces the device to enter the shutdown mode. Turning this terminal signal High (2.0V or higher) enables the device. The EN terminal must be properly terminated.
3	BST	Terminal for bootstrap. Connect a bootstrap capacitor of 0.1µF between this terminal and SW terminal. The voltage of the bootstrap capacitor is the gate drive voltage of the High-Side MOSFET.
4	SW	Switch terminal. The SW terminal is connected to the source of the High-Side MOSFET and drain of the Low-Side MOSFET. Connect a bootstrap capacitor of 0.1µF between the SW terminal and BST terminal. In addition, connect an inductor of 1.5µH considering the direct current superimposition characteristic.
5	MODE	Terminal for setting switching control mode. Turning this terminal signal Low (0.2V or lower) forces the device to operate in fixed frequency PWM mode. Turning this terminal signal High (0.8V or higher) enables the SLLM control and the mode is automatically switched between SLLM control and fixed frequency PWM mode. Do not change this terminal voltage during operation.
6	ITH	Terminal for the output of the error amplifier and the input of the current comparator. Connect phase compensation components to this terminal.
7	FB	Inverting input terminal for the error amplifier.
8	GND	Ground terminal for the output stage of the switching regulator and the control circuit.
-	E-PAD	Backside heat dissipation pad. Connecting to the PCB ground plane by using multiple vias provides excellent heat dissipation characteristics.

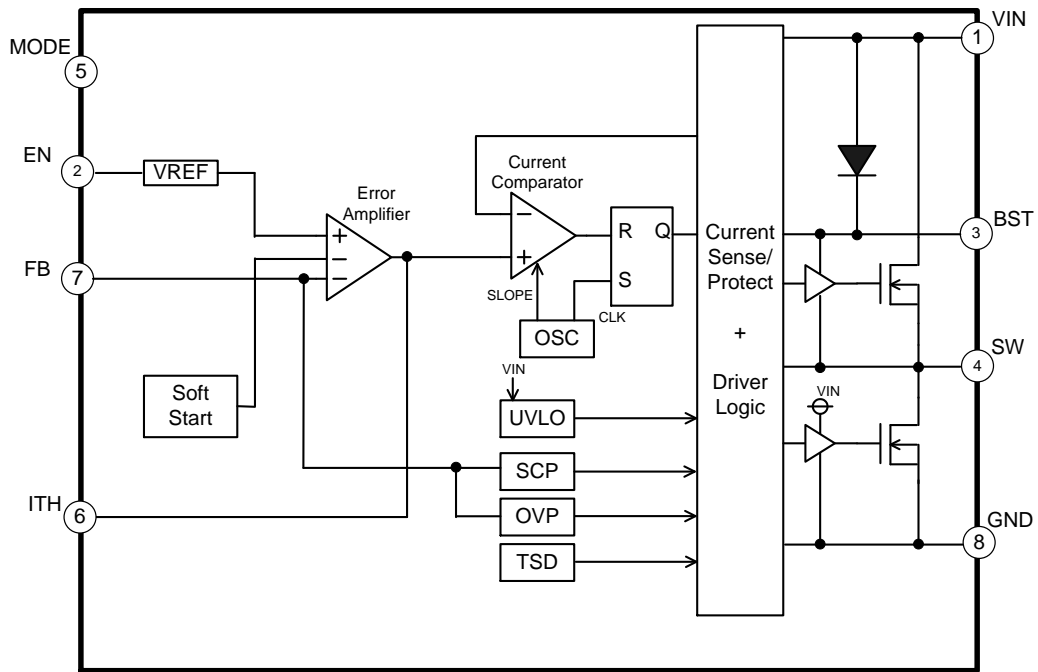**Block Diagram**

Figure 3. Block Diagram

Description of Blocks

1. VREF
   The VREF block generates the internal reference voltage.

2. UVLO
   The UVLO block is for under voltage lockout protection. It will shut down the IC when the VIN terminal voltage falls to 2.45V (Typ) or lower. The threshold voltage has a hysteresis of 100mV (Typ).

3. SCP
   After the soft start is completed and when the feedback voltage of the output voltage has fallen below 0.4V (Typ) for 1ms (Typ), the SCP stops the operation for 16ms (Typ) and subsequently initiates restart.

4. OVP
   The over voltage protection function (OVP) compares the FB terminal voltage with the internal reference voltage. When the FB terminal voltage exceeds 0.88V (Typ), it turns the output MOSFETs off. The output voltage returns with hysteresis after the output voltage drops to normal operation level.

5. TSD
   The TSD block is for thermal protection. The thermal protection circuit shuts down the device when the internal temperature of IC rises to 175°C (Typ) or higher. Thermal protection circuit resets when the temperature falls. The circuit has a hysteresis of 25°C (Typ).

6. Soft Start
   When EN terminal is switched High, Soft Start operates and the output voltage gradually rises. With the Soft Start Function, overshoot of output voltage and rush current can be prevented. The internal soft start time is set to 1ms (Typ).

7. Error Amplifier
   The error amplifier block compares the internal reference voltage with the feedback voltage of the output voltage. The error and the ITH terminal voltage determine the switching duty. A soft start is applied at startup. The ITH terminal voltage is limited by the internal slope voltage.

8. Current Comparator
   The Current Comparator block compares the output ITH terminal voltage of the error amplifier and the slope block signal to determine the switching duty. In the event of over current, the current that flows through the High-Side MOSFET is limited at each cycle of the switching frequency.

9. OSC
   This block is the oscillator.

10. Driver Logic
    This block is the DC/DC driver. A signal from current comparator is applied to drive the MOSFETs.

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Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Input Voltage	V_{IN}	-0.3 to +7	V
EN Terminal Voltage	V_{EN}	-0.3 to +7	V
MODE Terminal Voltage	V_{MODE}	-0.3 to +7	V
Voltage from GND to BST	V_{BST}	-0.3 to +14	V
Voltage from SW to BST	ΔV_{BST}	-0.3 to +7	V
FB Terminal Voltage	V_{FB}	-0.3 to +7	V
ITH Terminal Voltage	V_{ITH}	-0.3 to +7	V
SW Terminal Voltage	V_{SW}	-0.3 to V_{IN} + 0.3	V
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C

Caution1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.
Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

Thermal Resistance (Note 1)

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s(Note 3)	2s2p(Note 4)	
UMMP008AZ020				
Junction to Ambient	θ_{JA}	376.0	67.8	°C/W
Junction to Top Characterization Parameter(Note 2)	Ψ_{JT}	92.0	18.0	°C/W

(Note 1) Based on JESD51-2A (Still-Air)
(Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3) Using a PCB board based on JESD51-3.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3mm x 76.2mm x 1.57mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70μm

(Note 4) Using a PCB board based on JESD51-5, 7.

Layer Number of Measurement Board	Material	Board Size	Thermal Via(Note 5)	
			Pitch	Diameter
4 Layers	FR-4	114.3mm x 76.2mm x 1.6mmt	-	Φ0.30mm

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70μm	74.2mm x 74.2mm	35μm	74.2mm x 74.2mm	70μm

(Note 5) This thermal via connects with the copper pattern of all layers.

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Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Input Voltage	V_{IN}	2.7	-	5.5	V
Operating Temperature Range	Topr	-40	-	+85	°C
Output Current	I_{OUT}	0	-	3	A
Output Voltage Range	V_{RANGE}	0.8	-	V_{IN} x 0.7	V

Electrical Characteristics (Unless otherwise specified Ta = 25°C, V_{IN} = 5V, V_{EN} = 5V)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
INPUT SUPPLY						
Standby Supply Current	I_{STB}	-	0	10	µA	V_{EN} = GND
Operating Supply Current	I_{CC}	-	350	500	µA	I_{OUT} = 0mA Non-switching
UVLO Detection Voltage	V_{UVLO1}	2.35	2.45	2.55	V	V_{IN} Falling
UVLO Release Voltage	V_{UVLO2}	2.425	2.55	2.7	V	V_{IN} Rising
ENABLE						
EN Input High Level Voltage	V_{ENH}	2.0	-	V_{IN}	V	
EN Input Low Level Voltage	V_{ENL}	GND	-	0.8	V	
EN Input Current	I_{EN}	-	5	10	µA	V_{EN} = 5V
MODE						
MODE Threshold Voltage	V_{MODEH}	0.2	0.4	0.8	V	
MODE Input Current	I_{MODE}	-	10	20	µA	V_{MODE} = 5V
Reference Voltage, Error Amplifier						
FB Terminal Voltage	V_{FB}	0.792	0.8	0.808	V	
FB Input Current	I_{FB}	-	0	1	µA	V_{FB} = 0.8V
ITH Sink Current	I_{THSI}	10	20	40	µA	V_{FB} = 0.9V
ITH Source Current	I_{THSO}	10	20	40	µA	V_{FB} = 0.7V
Soft Start Time	t_{SS}	0.5	1.0	2.0	ms	
SWITCHING FREQUENCY						
Switching Frequency	f_{OSC}	800	1000	1200	kHz	
SWITCH MOSFET						
High Side FET ON Resistance	R_{ONH}	-	50	100	mΩ	$V_{BST} - V_{SW}$ = 5V
Low Side FET ON Resistance	R_{ONL}	-	50	100	mΩ	
High Side Output Leakage Current	I_{LH}	-	0	10	µA	Non-switching
Low Side Output Leakage Current	I_{LL}	-	0	10	µA	Non-switching
SCP						
Short Circuit Protection Detection Voltage	V_{SCP}	0.28	0.4	0.52	V	

Typical Performance Curves
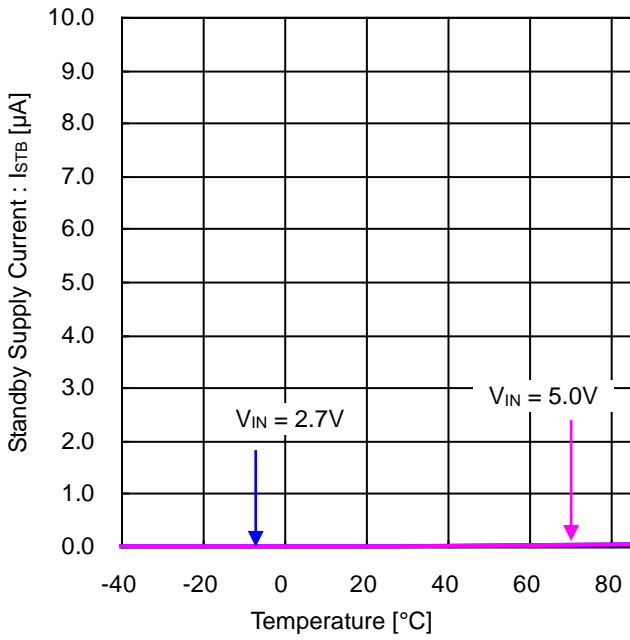
Figure 4. Standby Supply Current vs Temperature
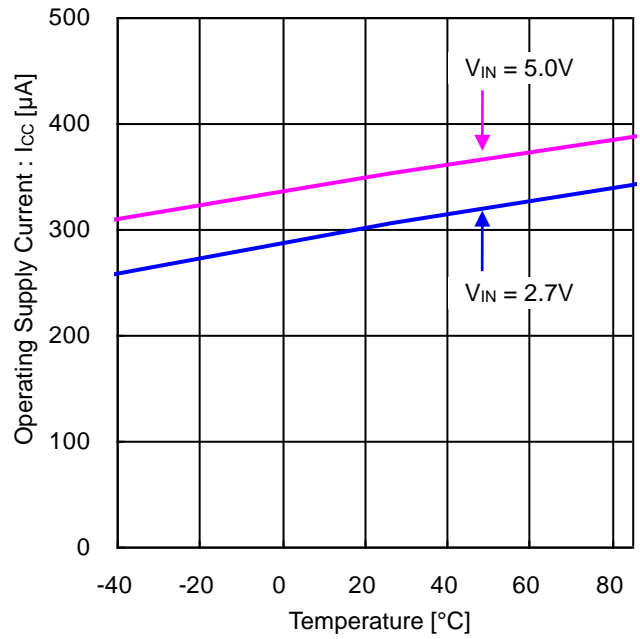

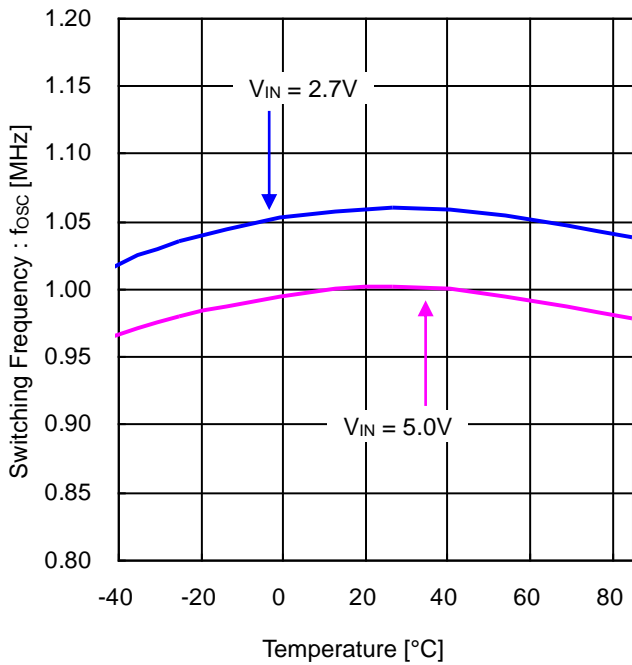Figure 5. Operating Supply Current vs Temperature

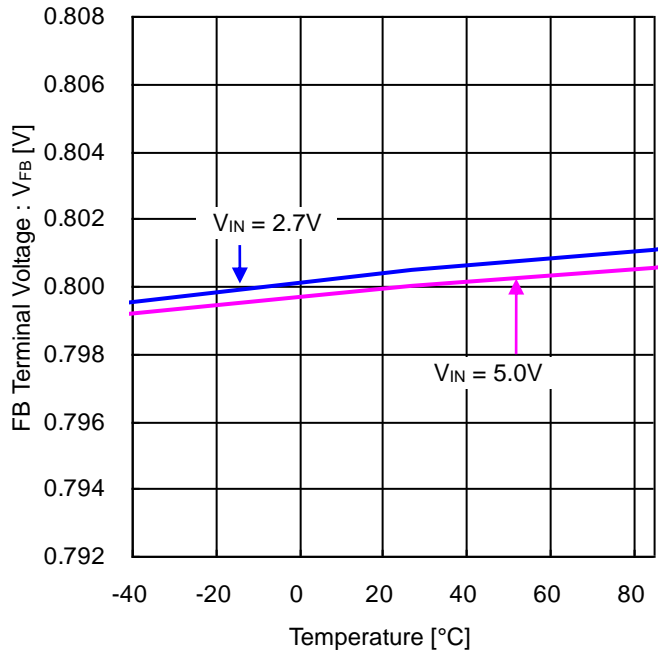Figure 6. Switching Frequency vs Temperature

Figure 7. FB Terminal Voltage vs Temperature

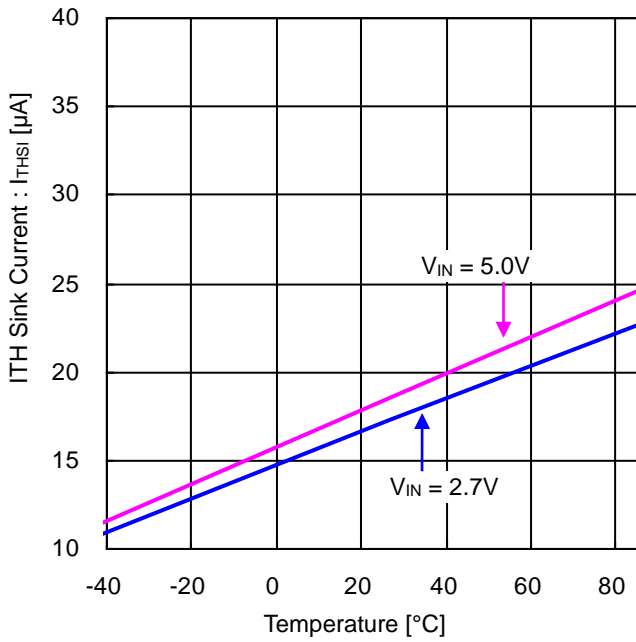## Typical Performance Curves - continued
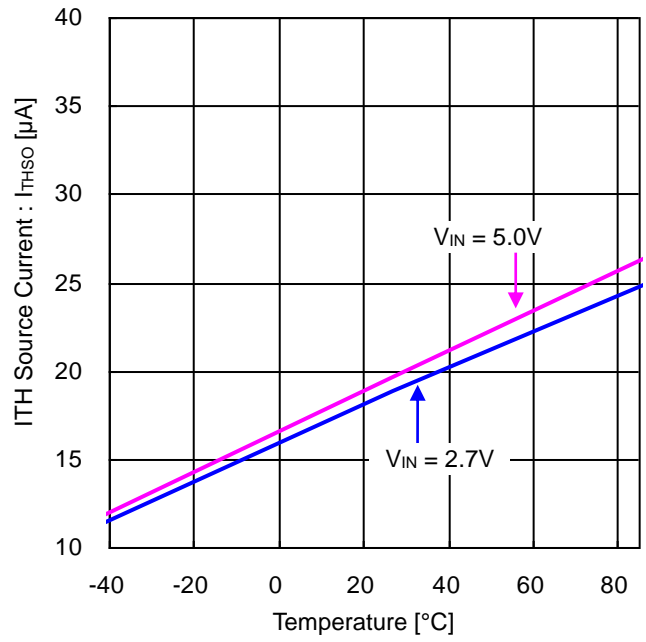

Figure 8. ITH Sink Current vs Temperature

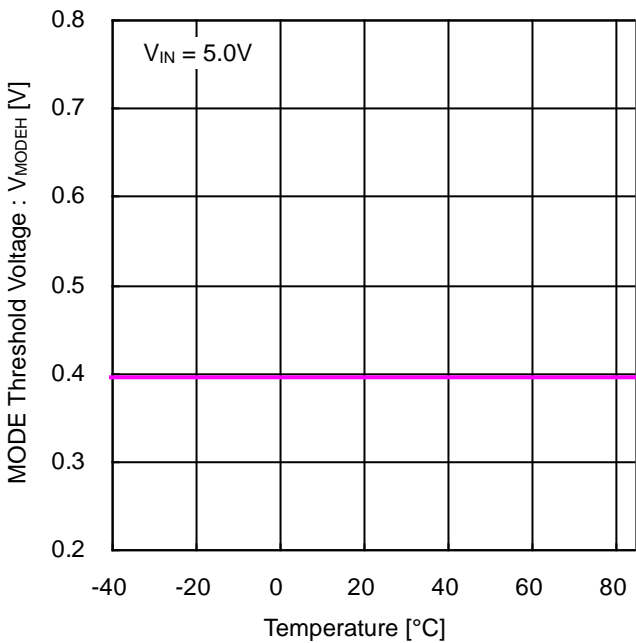Figure 9. ITH Source Current vs Temperature
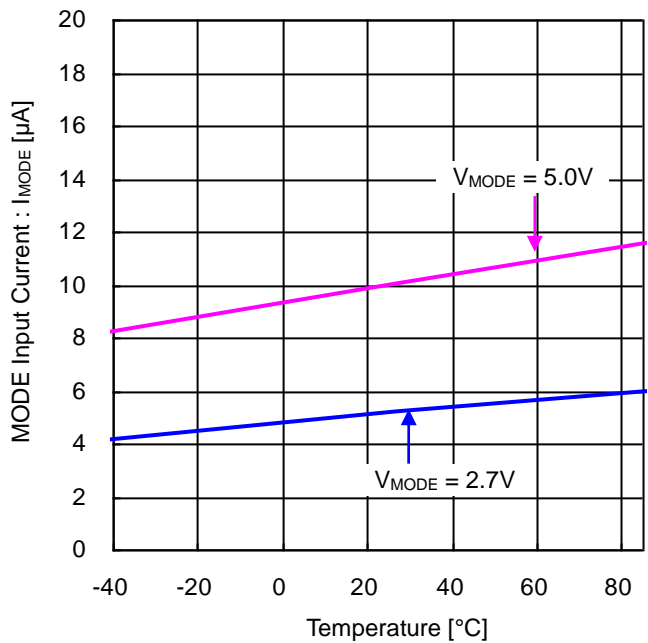

Figure 10. MODE Threshold Voltage vs Temperature
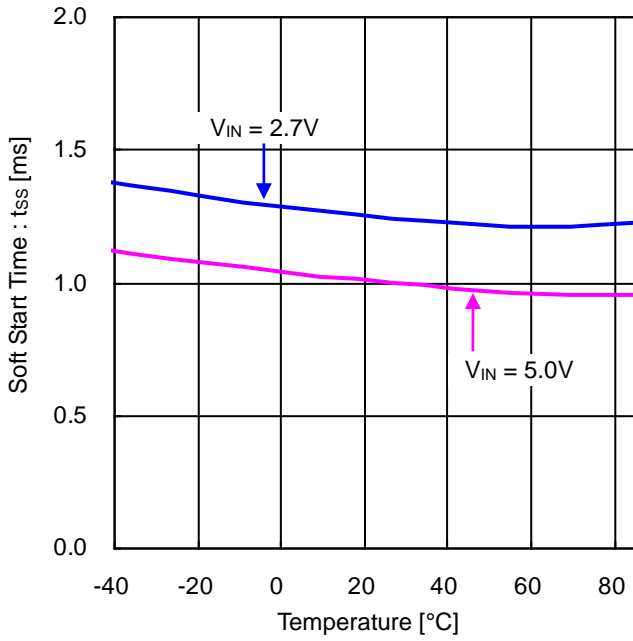

Figure 11. MODE Input Current vs Temperature

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Typical Performance Curves - continued

Figure 12. Soft Start Time vs Temperature
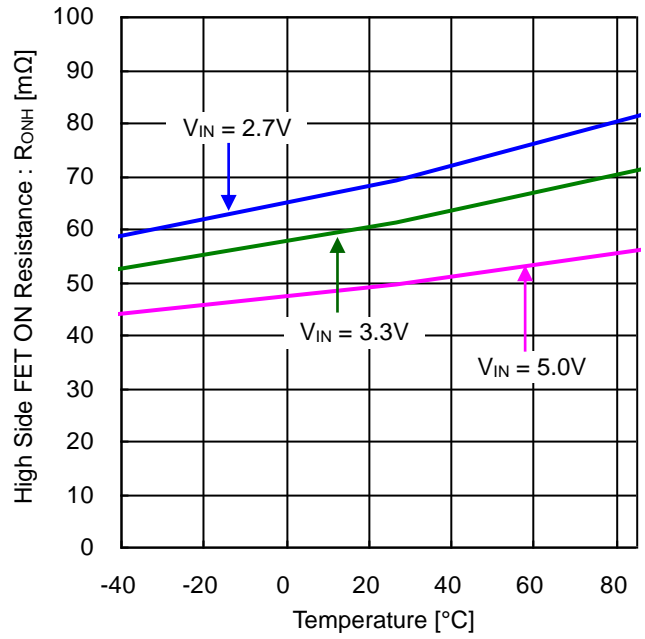
Figure 13. High Side FET ON Resistance vs Temperature
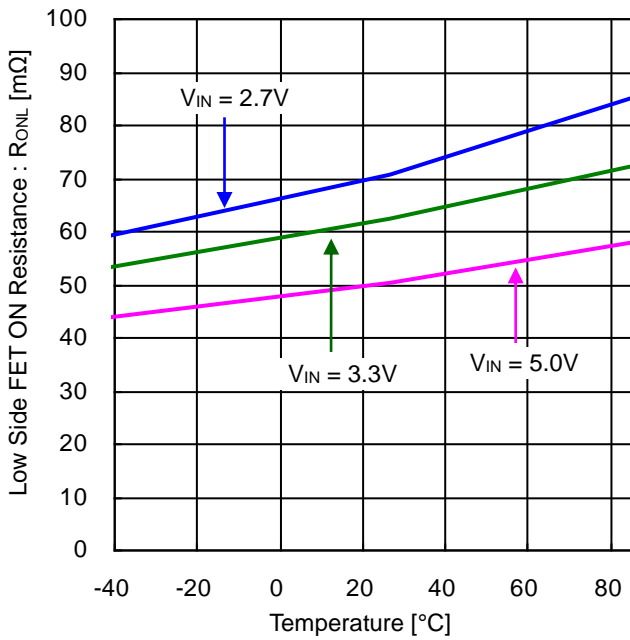
Figure 14. Low Side FET ON Resistance vs Temperature
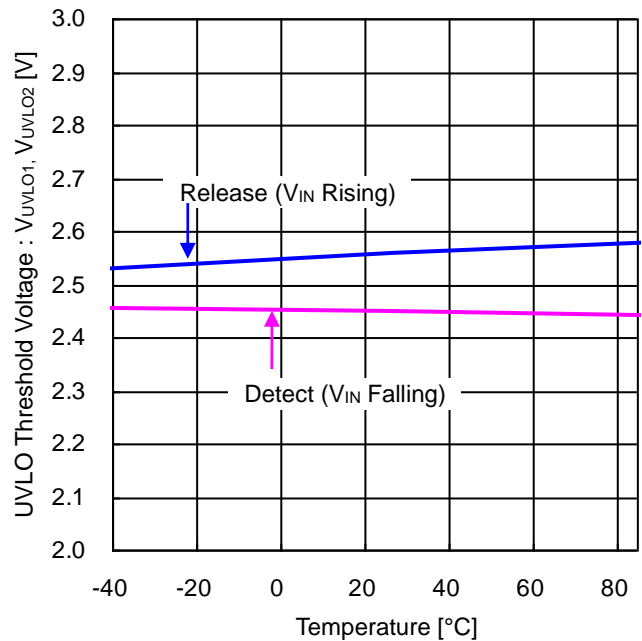
Figure 15. UVLO Detection / Release Voltage
vs Temperature

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Typical Performance Curves - continued

Figure 16. EN Threshold Voltage vs Temperature
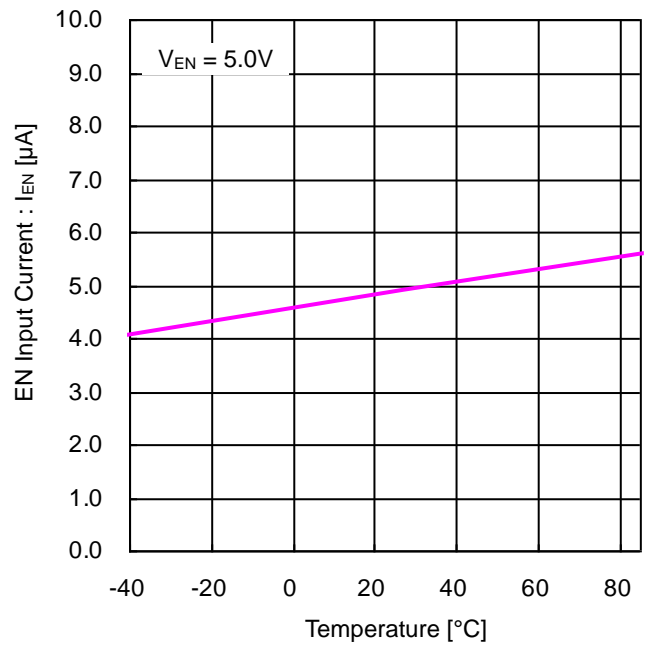
Figure 17. EN Input Current vs Temperature

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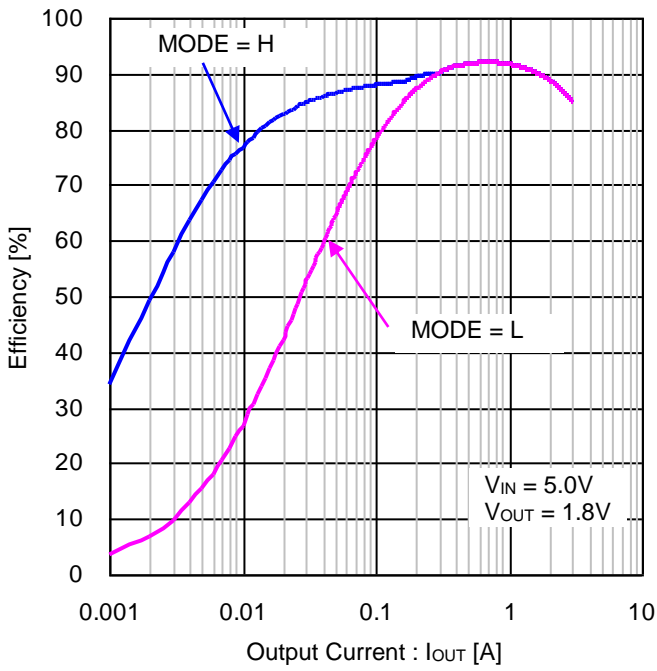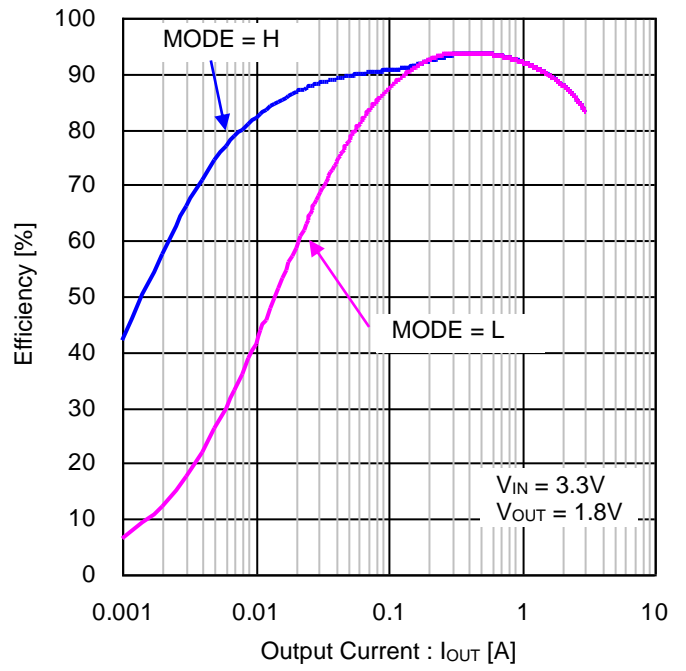
Typical Performance Curves (Application)

Figure 18. Efficiency vs Output Current
(VIN = 5V, VOUT = 1.8V, L = 1.5µH)

Figure 19. Efficiency vs Output Current
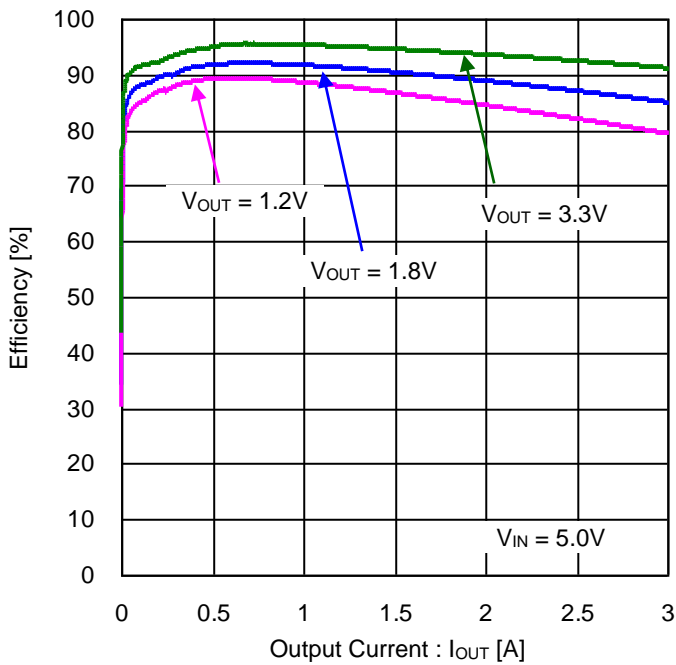(V_{IN} = 3.3V, V_{OUT} = 1.8V, L = 1.5µH)

Figure 20. Efficiency vs Output Current
(V_{IN} = 5.0V, V_{MODE} = 5.0V, L = 1.5µH)
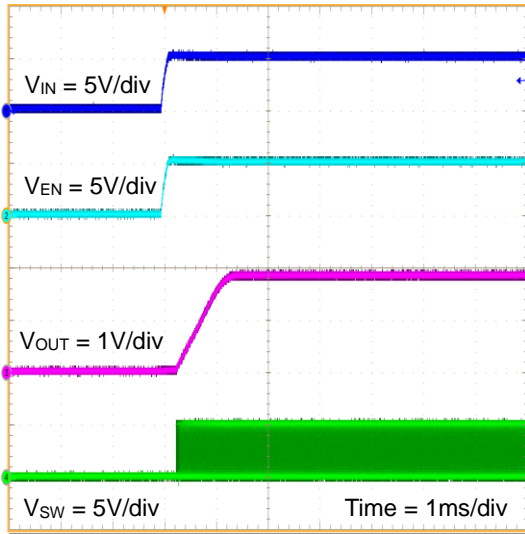
Typical Performance Curves (Application) - continued

Figure 21. Start-up Waveform (V$_{IN}$ = V$_{EN}$)
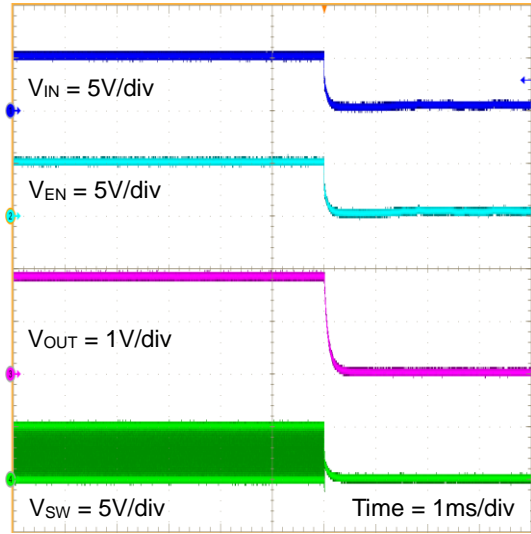(V$_{OUT}$ = 1.8V, V$_{MODE}$ = V$_{IN}$, R$_{LOAD}$ = 0.6Ω)

Figure 22. Shutdown Waveform (V$_{IN}$ = V$_{EN}$)
(V$_{OUT}$ = 1.8V, V$_{MODE}$ = V$_{IN}$, R$_{LOAD}$ = 0.6Ω)
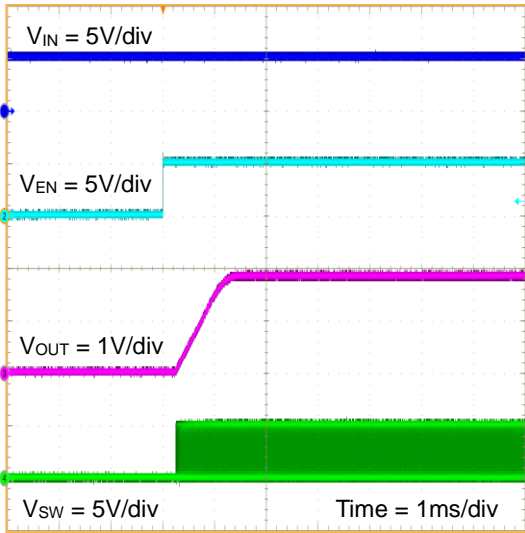

Figure 23. Start-up Waveform (V$_{EN}$ = 0V to 5V)
(V$_{OUT}$ = 1.8V, V$_{MODE}$ = V$_{IN}$, R$_{LOAD}$ = 0.6Ω)

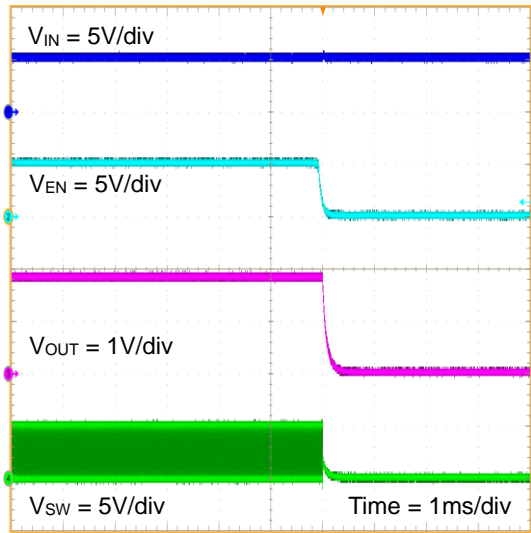Figure 24. Shutdown Waveform (V$_{EN}$ = 5V to 0V)
(V$_{OUT}$ = 1.8V, V$_{MODE}$ = V$_{IN}$, R$_{LOAD}$ = 0.6Ω)

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Typical Performance Curves (Application) - continued

Figure 25. Output Voltage Ripple
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 0A)

Figure 26. Output Voltage Ripple
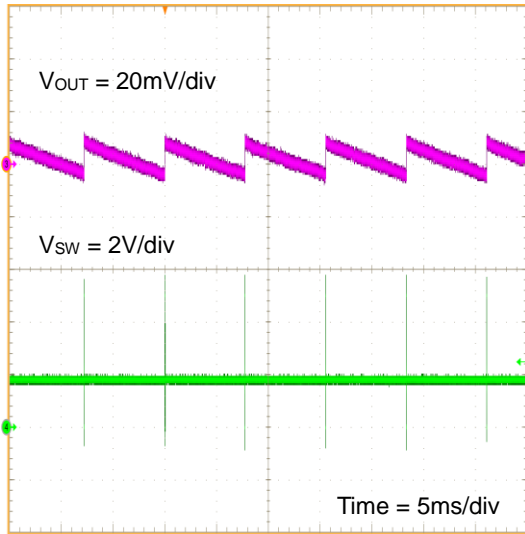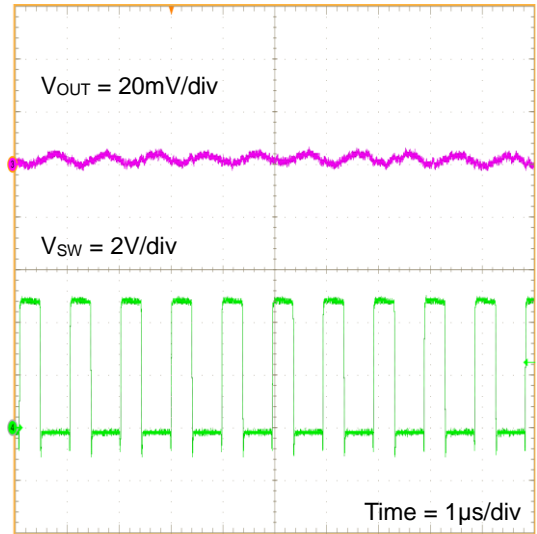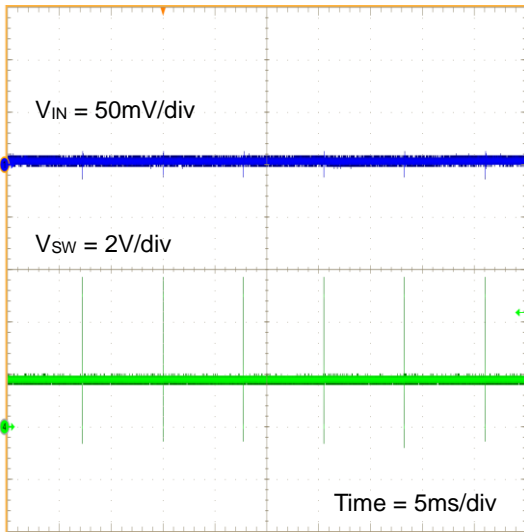(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 3A)

Figure 27. Input Voltage Ripple
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 0A)
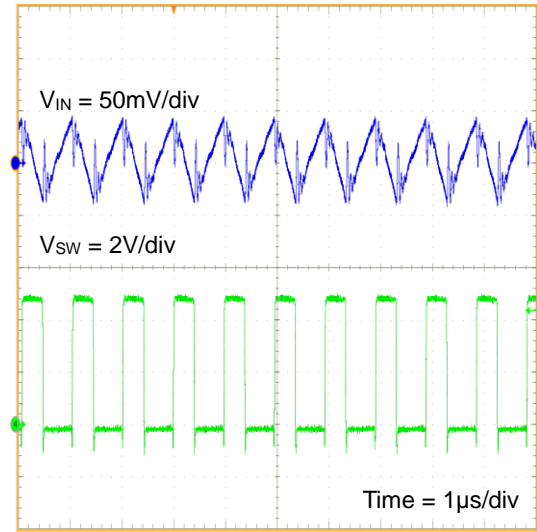

Figure 28. Input Voltage Ripple
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 3A)

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Typical Performance Curves (Application) - continued
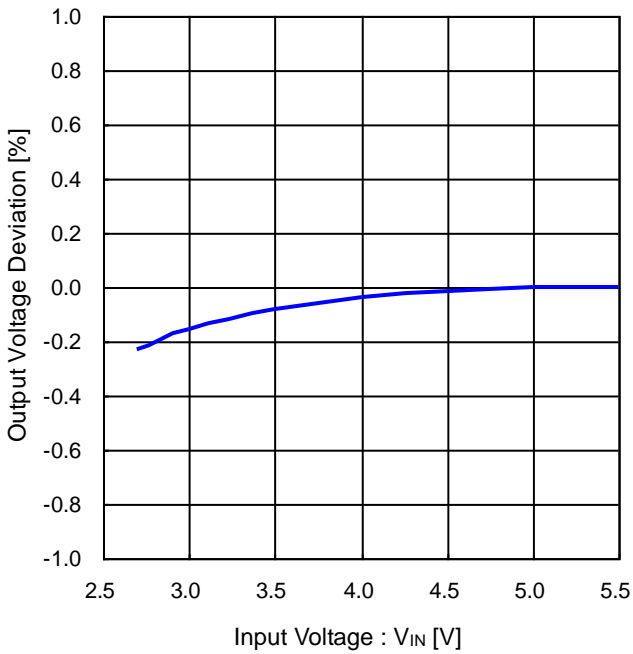
Figure 29. Line Regulation
(V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT}=3A)
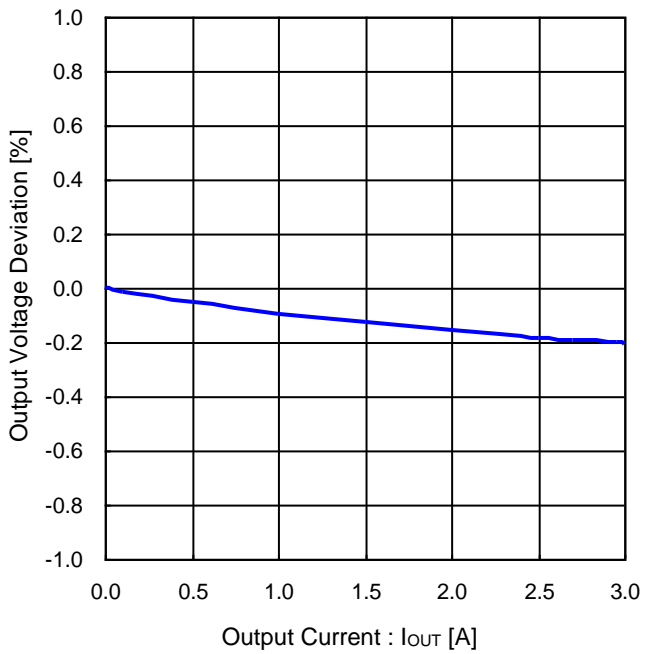
Figure 30. Load Regulation
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN})

Figure 31. Load Transient Response
I_{OUT} = 0.75A - 2.25A
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, C_{OUT} = 22μF x 2)

Figure 32. Load Transient Response
I_{OUT} = 0A - 3A
(V_{IN} = 5V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, C_{OUT} = 22μF x 2)

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Application Information

1. Function Explanations

(1) Basic Operation

(a) DC/DC Converter Operation

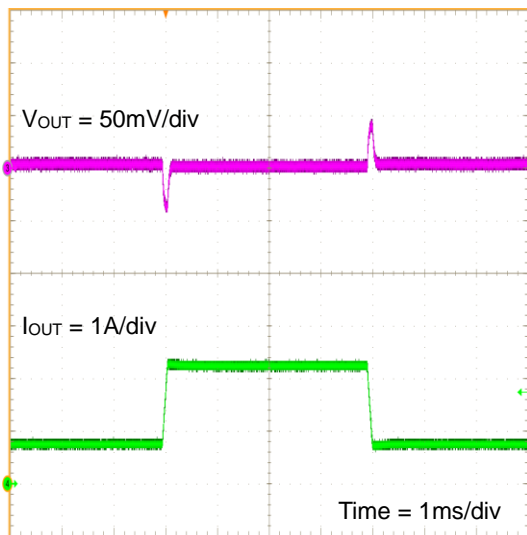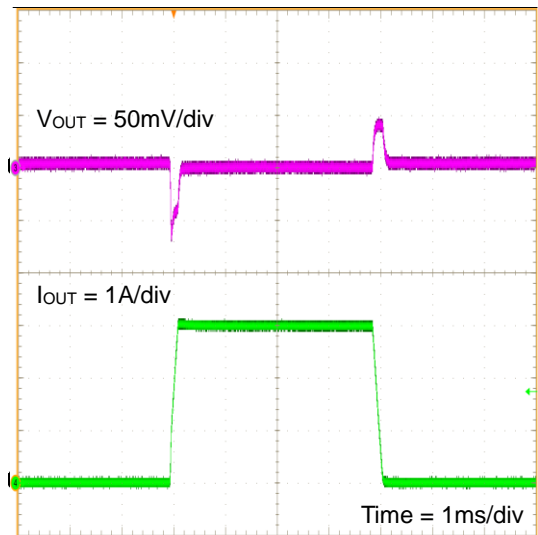BD9A302QWZ is a synchronous rectifying buck DC/DC converter that achieves fast load transient response by employing current mode control system. It utilizes switching operation in PWM (Pulse Width Modulation) mode for heavy load, while it utilizes SLLM (Simple Light Load Mode) control for light load to improve efficiency.
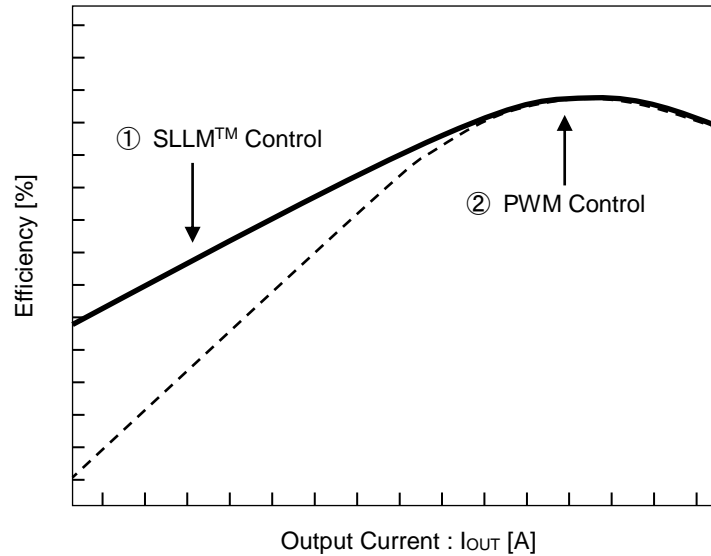
Figure 33. Efficiency (SLLM[TM] Control and PWM Control)

①SLLM[TM] Control

②PWM Control

V_{OUT} = 50mV/div

V_{SW} = 2V/div

Time = 2μs/div
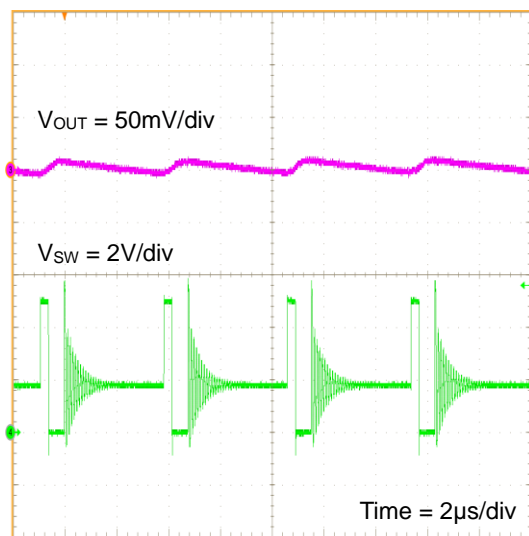
Figure 34. SW Waveform (SLLM[TM] Control)
(V_{IN} = 5.0V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 50mA)

V_{OUT} = 50mV/div

V_{SW} = 2V/div

Time = 2μs/div
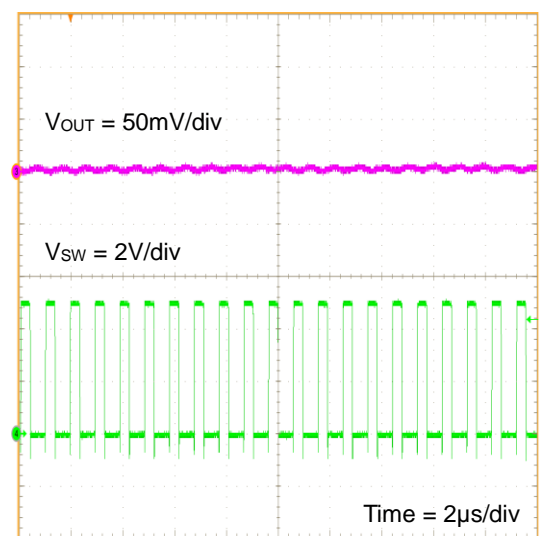
Figure 35. SW Waveform (PWM Control)
(V_{IN} = 5.0V, V_{OUT} = 1.8V, V_{MODE} = V_{IN}, I_{OUT} = 1A)

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(b) Enable Control

The IC shutdown can be controlled by the voltage applied to the EN terminal. When V_{EN} reaches 2.0V (Min), the internal circuit is activated and the IC starts up. To enable shutdown control with the EN terminal, the shutdown interval (low level interval of EN) must be set to 100µs or longer. Startup by EN must be at the same time or after the input of power supply voltage.
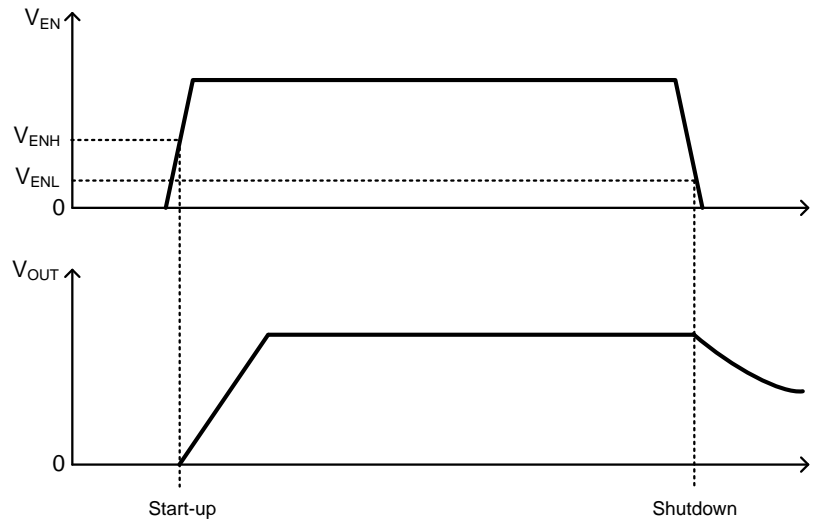
Figure 36. Start-up and Shutdown with Enable

(c) Soft Start

When EN terminal is switched High, Soft Start operates and the output voltage gradually rises. With the Soft Start Function, overshoot of output voltage and rush current can be prevented. The rising time of output voltage is 1ms (Typ).

Figure 37. Soft Start Timing Chart

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(2) Protection
The protective circuits are intended for prevention of damage caused by unexpected accidents.
Do not use them for continuous protective operation.

(a) Short Circuit Protection (SCP)
The short circuit protection block compares the FB terminal voltage with the internal reference voltage V_{REF}.
When the FB terminal voltage has fallen below 0.4V (Typ) for 1ms (Typ), SCP stops the operation for 16ms
(Typ) and subsequently initiates a restart. However, during start-up, short circuit protection does not operate
even if the IC is still in the SCP condition.

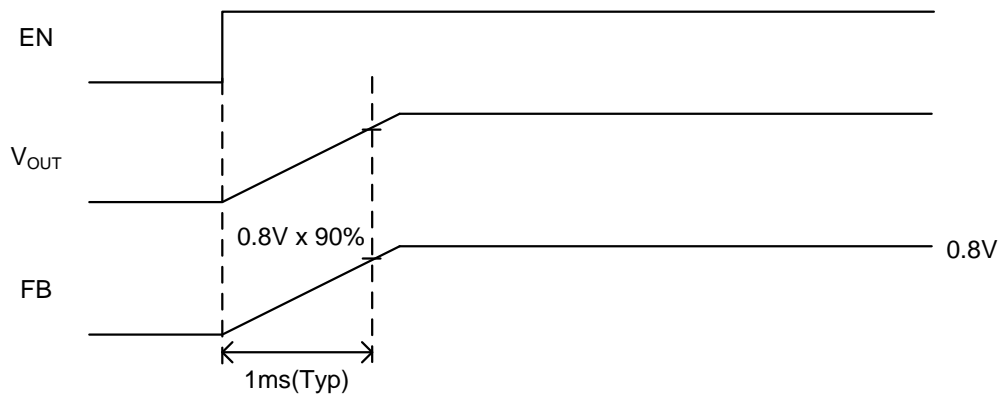| EN Terminal	Start-up Condition	FB Terminal	Short Circuit Protection
2.0V or higher	During start-up	≤ 0.4V (Typ)	OFF
		> 0.4V (Typ)	OFF
	Completed start-up	≤ 0.4V (Typ)	ON
		> 0.4V (Typ)	OFF
0.8V or lower	-	-	OFF

Figure 38. Short Circuit Protection (SCP) Timing Chart

(b) Under Voltage Lockout Protection (UVLO)

The Under Voltage Lockout Protection circuit monitors the VIN terminal voltage. The operation enters standby when the VIN terminal voltage is 2.45V (Typ) or lower. The operation starts when the VIN terminal voltage is 2.55V (Typ) or higher.
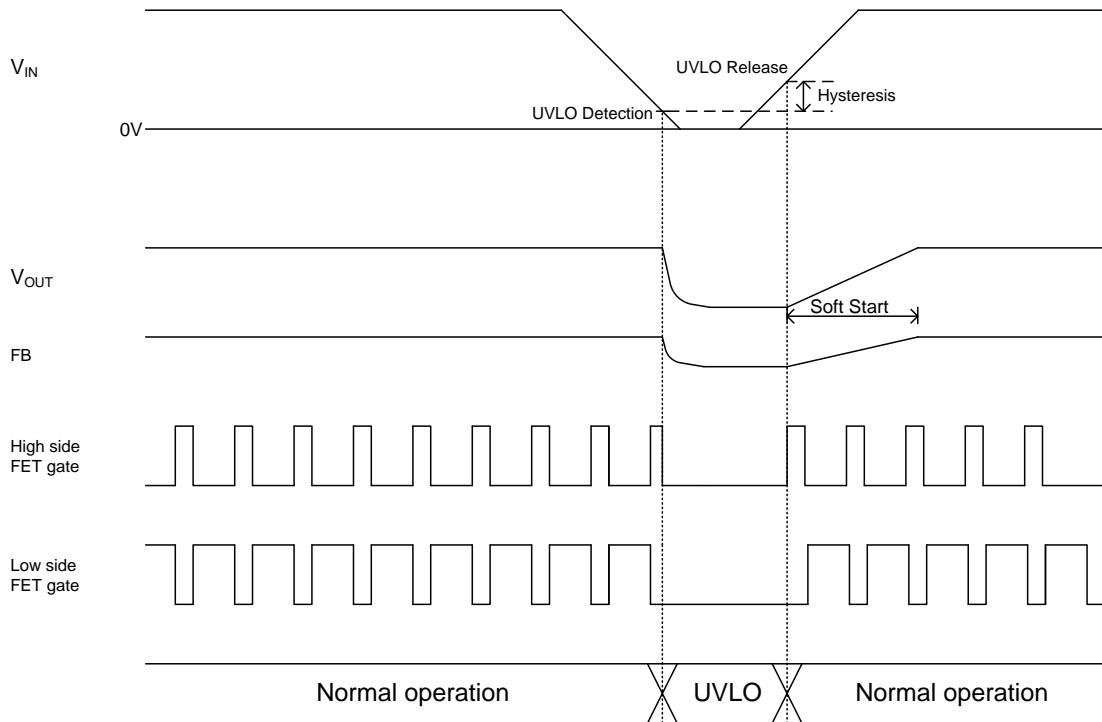

Figure 39. UVLO Timing Chart

(c) Thermal Shutdown (TSD)

When the chip temperature exceeds Tj = 175°C (Typ), the DC/DC converter output is stopped. Thermal protection circuit is reset when the temperature falls down. The thermal shutdown circuit is intended for shutting down the IC from thermal runaway in an abnormal state with the temperature exceeding Tjmax = 150°C. It is not meant to protect or guarantee the reliability of the application. Do not use this function of the circuit for application protection design.

(d) Over Current Protection (OCP)

The Over Current Protection function operates by using the current mode control to limit the current that flows through the high-side MOSFET at each cycle of the switching frequency. The designed over current limit value is 6.0A (Typ).

(e) Over Voltage Protection (OVP)

The over voltage protection function (OVP) compares the FB terminal voltage with the internal reference voltage V_{REF}. When the FB terminal voltage exceeds 0.88V (Typ), it turns the output MOSFETs off. The output voltage returns to normal operation level with hysteresis after the output voltage drops.

2.   Application Example (V_{OUT}=3.3V)

Parameter	Symbol	Value
Input Voltage	V_{IN}	5V
Output Voltage	V_{OUT}	3.3V
Switching Frequency	f_{OSC}	1MHz (Typ)
Maximum Output Current	I_{OUTMAX}	3A
Operating Temperature Range	Topr	-40°C to +85°C
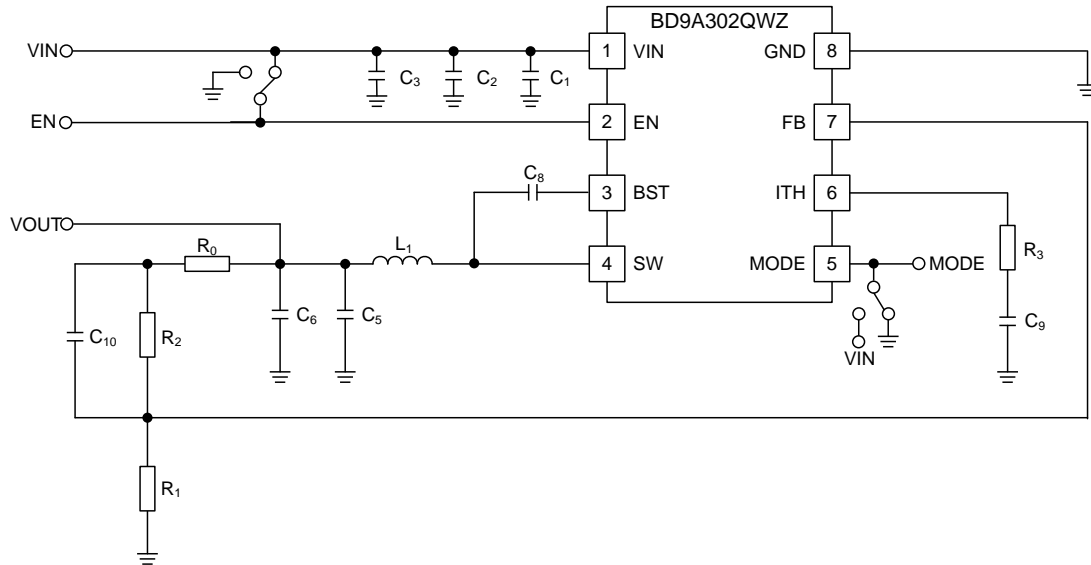
Figure 40. Application Circuit

Table 1. Recommended Component Values

Part No.	Value	Company	Part Name
L_1	1.5µH	Murata	FDSD0420-H-1R5M
C_1 (Note 1)	0.1µF	Murata	GRM155B11A104MA01
C_2 (Note 2)	10µF	Murata	GRM21BB31A106ME18
C_3	-	-	-
C_5 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_6 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_8 (Note 4)	0.1µF	Murata	GRM155B11A104MA01
C_9	2700pF	Murata	GRM155B11H272KA01
C_{10}	-	-	-
R_0	0Ω	ROHM	MCR01MZPJ000
R_1	24kΩ	ROHM	MCR01MZPD2402
R_2	75kΩ	ROHM	MCR01MZPD7502
R_3	18kΩ	ROHM	MCR01MZPD1802

(Note 1) In order to reduce the influence of high frequency noise, mount the 0.1µF ceramic capacitor as close as possible to the VIN pin and GND pin.
(Note 2) For the capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set to a minimum value of no less than 4.7µF.
(Note 3) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, loop response characteristics may change. Please confirm on actual equipment. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Ceramic type of capacitors is recommended for the output capacitors.
(Note 4) For capacitance of bootstrap capacitor take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value to no less than 0.047µF.
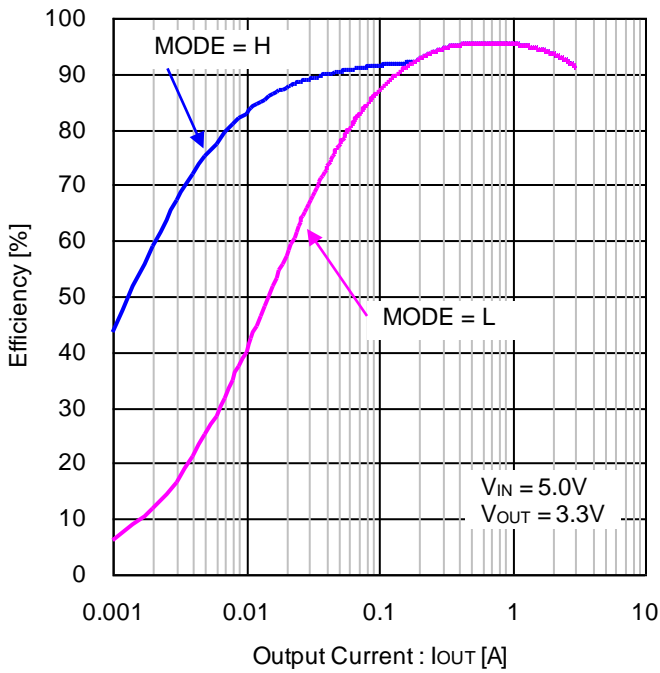
Figure 41. Efficiency vs Output Current
(V_{IN} = 5V, V_{OUT} = 3.3V, L = 1.5µH)
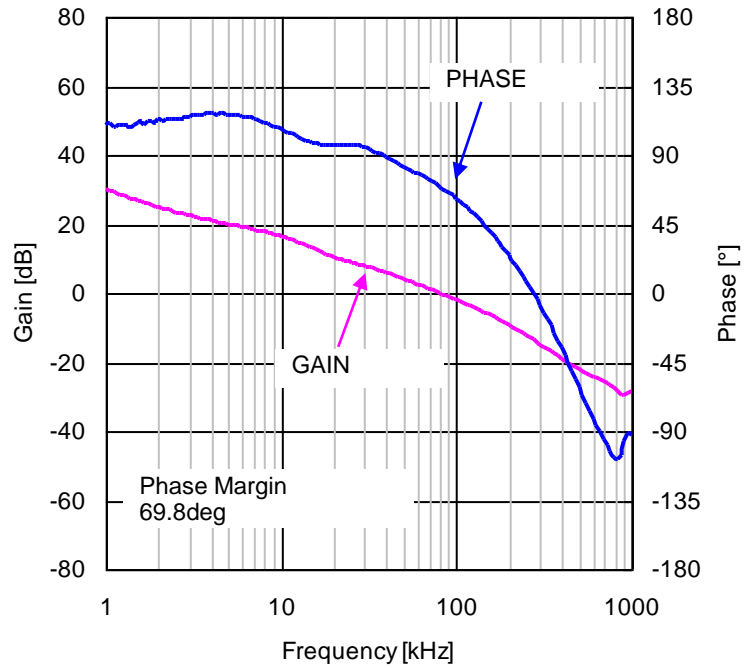

Figure 42. Closed Loop Response I_{OUT} = 1A
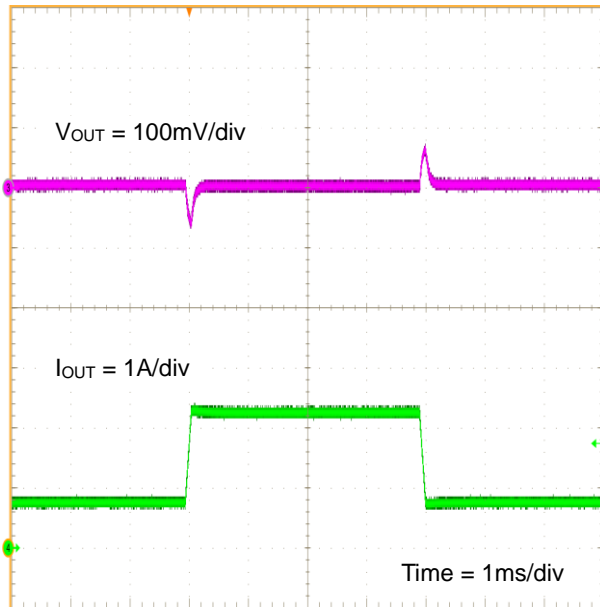(V_{IN} = 5V, V_{OUT} = 3.3V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 43. Load Transient Response
I_{OUT} = 0.75A – 2.25A
(V_{IN} = 5V, V_{OUT} = 3.3V, L = 1.5µH, C_{OUT} = 22µF x 2)

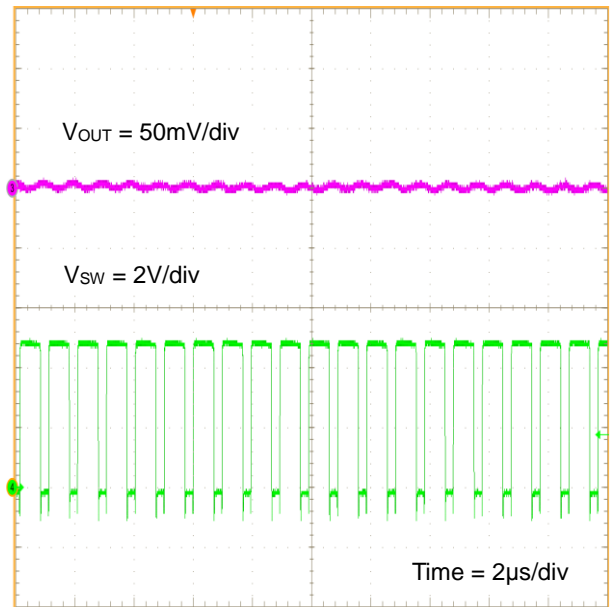Figure 44. V_{OUT} Ripple I_{OUT} = 3A
(V_{IN} = 5V, V_{OUT} = 3.3V, L = 1.5µH, C_{OUT}=22µF x 2)

3. Application Example (V_{OUT}=1.8V)

Parameter	Symbol	Value
Input Voltage	V_{IN}	5V
Output Voltage	V_{OUT}	1.8V
Switching Frequency	f_{OSC}	1MHz (Typ)
Maximum Output Current	I_{OUTMAX}	3A
Operating Temperature Range	Topr	-40°C to +85°C
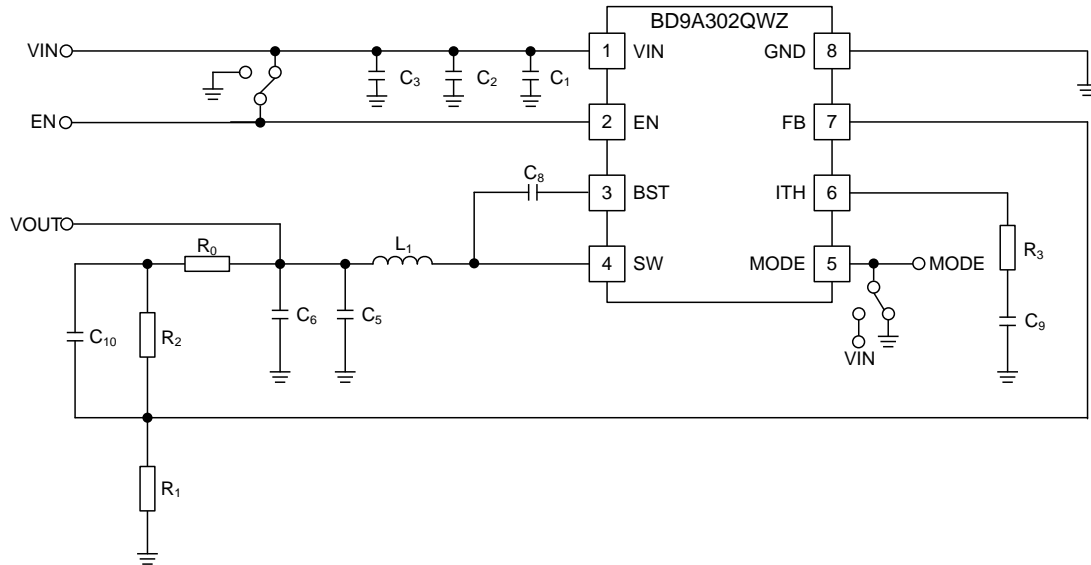
Figure 45. Application Circuit

Table 2. Recommended Component Values

Part No.	Value	Company	Part Name
L_1	1.5µH	Murata	FDSD0420-H-1R5M
C_1 (Note 1)	0.1µF	Murata	GRM155B11A104MA01
C_2 (Note 2)	10µF	Murata	GRM21BB31A106ME18
C_3	-	-	-
C_5 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_6 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_8 (Note 4)	0.1µF	Murata	GRM155B11A104MA01
C_9	2700pF	Murata	GRM155B11H272KA01
C_{10}	-	-	-
R_0	0Ω	ROHM	MCR01MZPJ000
R_1	24kΩ	ROHM	MCR01MZPD2402
R_2	30kΩ	ROHM	MCR01MZPD3002
R_3	9.1kΩ	ROHM	MCR01MZPD9101

(Note 1) In order to reduce the influence of high frequency noise, mount the 0.1µF ceramic capacitor as close as possible to the VIN pin and GND pin.

(Note 2) For the capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set to a minimum value of no less than 4.7µF.

(Note 3) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, loop response characteristics may change. Please confirm on actual equipment. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Ceramic type of capacitors is recommended for the output capacitors.

(Note 4) For capacitance of bootstrap capacitor take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value to no less than 0.047µF.

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Figure 46. Efficiency vs Output Current
(V_{IN} = 5V, V_{OUT} = 1.8V, L = 1.5µH)

Figure 47. Closed Loop Response I_{OUT} = 1A
(V_{IN} = 5V, V_{OUT} = 1.8V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 48. Load Transient Response
I_{OUT} = 0.75A – 2.25A
(V_{IN} = 5V, V_{OUT} = 1.8V, L = 1.5µH, C_{OUT} = 22µF x 2)
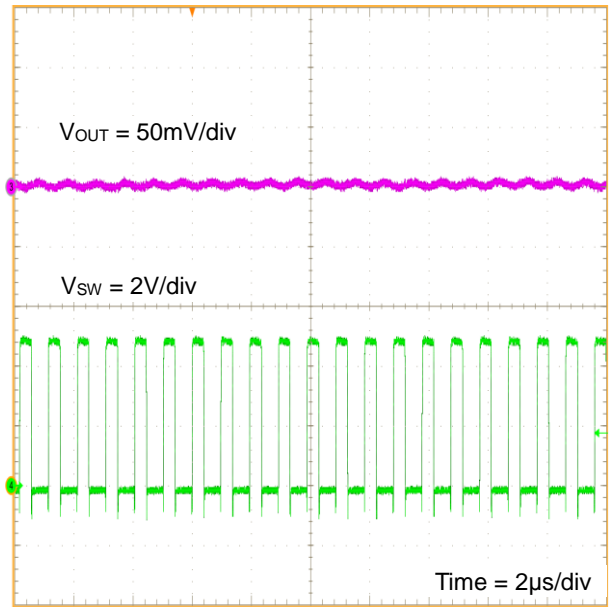
Figure 49. V_{OUT} Ripple I_{OUT} = 3A
(V_{IN} = 5V, V_{OUT} = 1.8V, L = 1.5µH, C_{OUT} = 22µF x 2)

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4. Application Example (V_OUT=1.5V)

Parameter	Symbol	Value
Input Voltage	V_{IN}	5V
Output Voltage	V_{OUT}	1.5V
Switching Frequency	f_{OSC}	1MHz (Typ)
Maximum Output Current	I_{OUTMAX}	3A
Operating Temperature Range	Topr	-40°C to +85°C
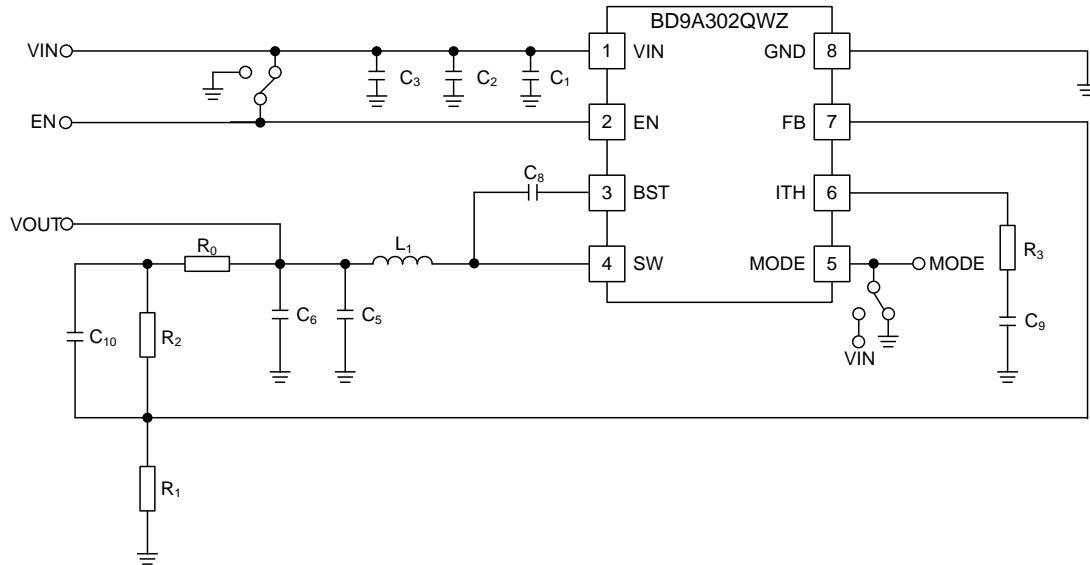
Figure 50. Application Circuit

Table 3. Recommended Component Values

Part No.	Value	Company	Part Name
L_1	1.5µH	Murata	FDSD0420-H-1R5M
C_1 (Note 1)	0.1µF	Murata	GRM155B11A104MA01
C_2 (Note 2)	10µF	Murata	GRM21BB31A106ME18
C_3	-	-	-
C_5 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_6 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_8 (Note 4)	0.1µF	Murata	GRM155B11A104MA01
C_9	2700pF	Murata	GRM155B11H272KA01
C_{10}	-	-	-
R_0	0Ω	ROHM	MCR01MZPJ000
R_1	18kΩ	ROHM	MCR01MZPD1802
R_2	16kΩ	ROHM	MCR01MZPD1602
R_3	9.1kΩ	ROHM	MCR01MZPD9101

(Note 1) In order to reduce the influence of high frequency noise, mount the 0.1µF ceramic capacitor as close as possible to the VIN pin and GND pin.
(Note 2) For the capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set to a minimum value of no less than 4.7µF.
(Note 3) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, loop response characteristics may change. Please confirm on actual equipment. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Ceramic type of capacitors is recommended for the output capacitors.
(Note 4) For capacitance of bootstrap capacitor take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value to no less than 0.047µF.
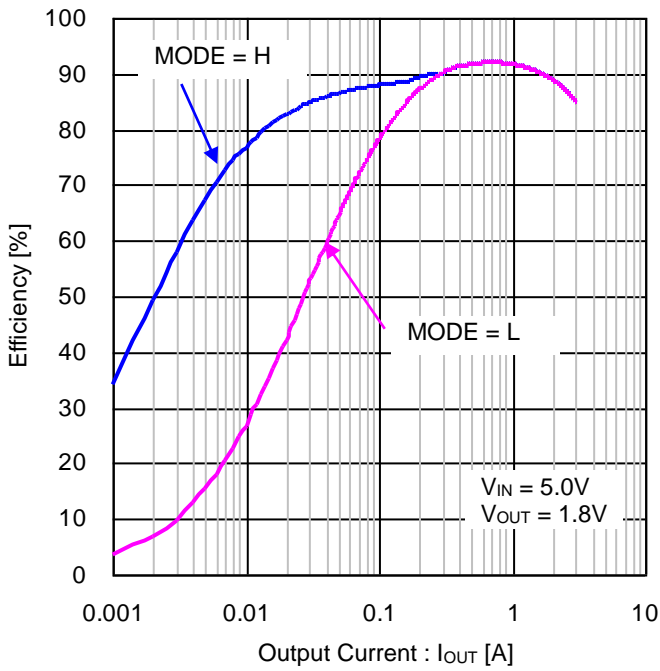
Figure 51. Efficiency vs Output Current
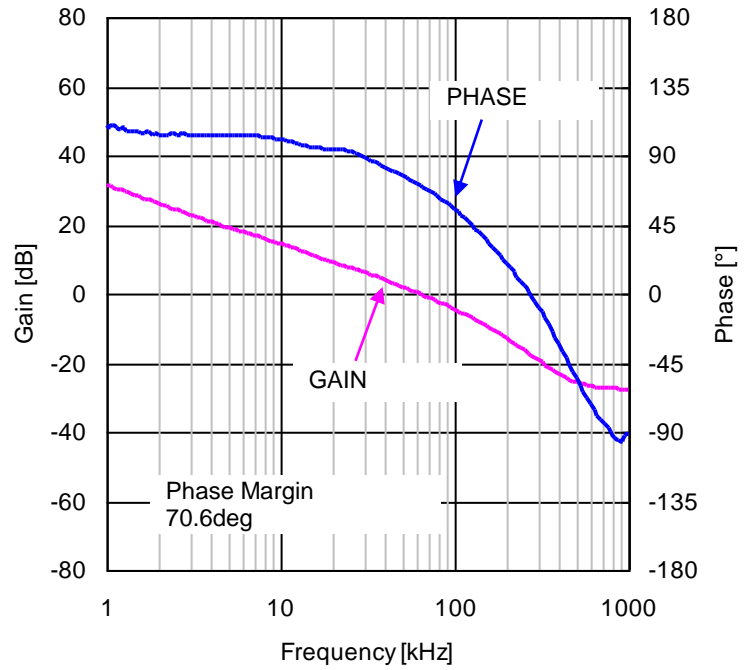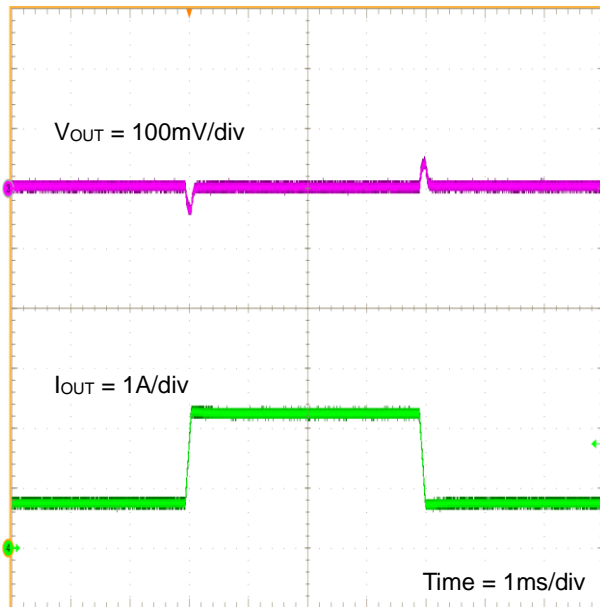(V_{IN} = 5V, V_{OUT} = 1.5V, L = 1.5µH)

Figure 52. Closed Loop Response I_{OUT} = 1A
(V_{IN} = 5V, V_{OUT} = 1.5V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 53. Load Transient Response
I_{OUT}=0.75A – 2.25A
(V_{IN} = 5V, V_{OUT} = 1.5V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 54. V_{OUT} Ripple I_{OUT} = 3A
(V_{IN} = 5V, V_{OUT} = 1.5V, L = 1.5µH, C_{OUT} = 22µF x 2)

5. Application Example (V_{OUT}=1.2V)

Parameter	Symbol	Value
Input Voltage	V_{IN}	5V
Output Voltage	V_{OUT}	1.2V
Switching Frequency	f_{OSC}	1MHz (Typ)
Maximum Output Current	I_{OUTMAX}	3A
Operating Temperature Range	Topr	-40°C to +85°C
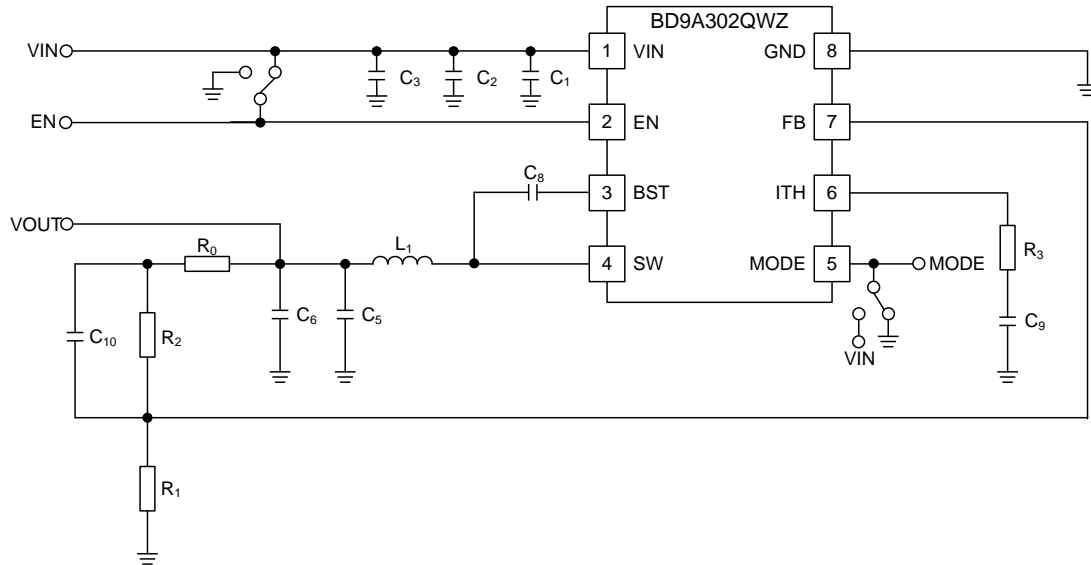
Figure 55. Application Circuit

Table 4. Recommended Component Values

Part No.	Value	Company	Part Name
L_1	1.5µH	Murata	FDSD0420-H-1R5M
C_1 (Note 1)	0.1µF	Murata	GRM155B11A104MA01
C_2 (Note 2)	10µF	Murata	GRM21BB31A106ME18
C_3	-	-	-
C_5 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_6 (Note 3)	22µF	Murata	GRM21BB30J226ME38
C_8 (Note 4)	0.1µF	Murata	GRM155B11A104MA01
C_9	2700pF	Murata	GRM155B11H272KA01
C_{10}	-	-	-
R_0	0Ω	ROHM	MCR01MZPJ000
R_1	20kΩ	ROHM	MCR01MZPD2002
R_2	10kΩ	ROHM	MCR01MZPD1002
R_3	8.2kΩ	ROHM	MCR01MZPD8201

(Note 1) In order to reduce the influence of high frequency noise, mount the 0.1µF ceramic capacitor as close as possible to the VIN pin and GND pin.
(Note 2) For the capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set to a minimum value of no less than 4.7µF.
(Note 3) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, loop response characteristics may change. Please confirm on actual equipment. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Ceramic type of capacitors is recommended for the output capacitors.
(Note 4) For capacitance of bootstrap capacitor take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value to no less than 0.047µF.
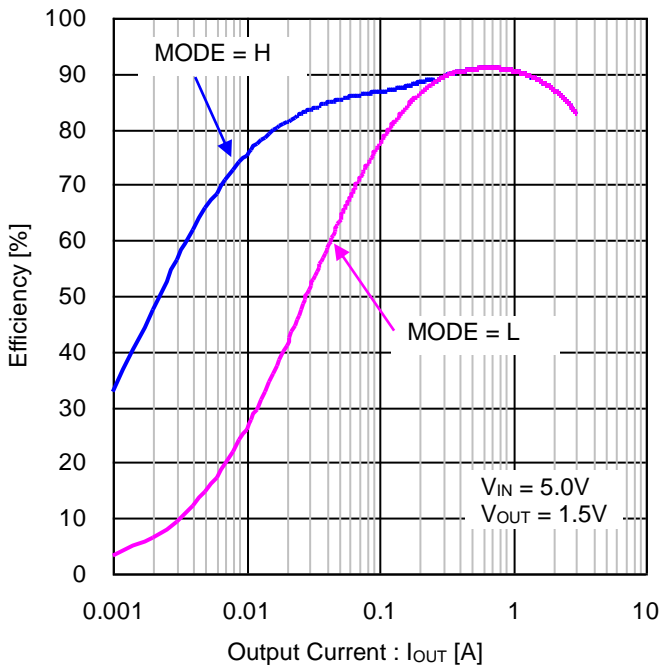
Figure 56. Efficiency vs Output Current
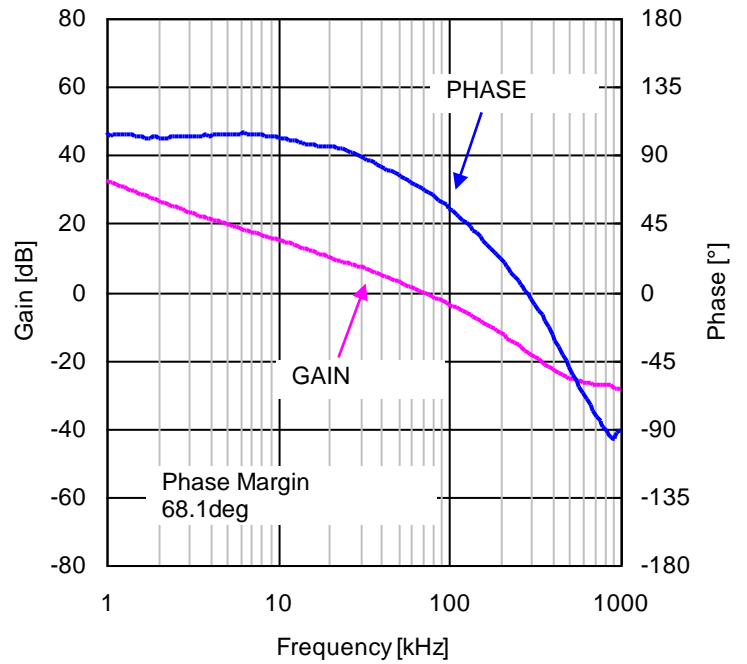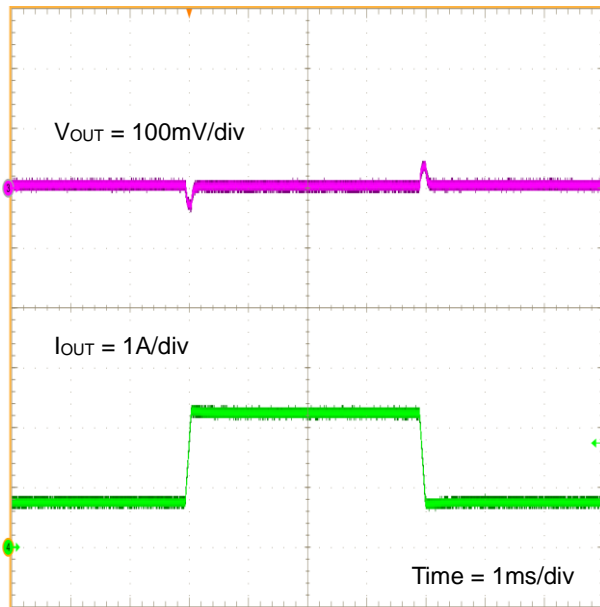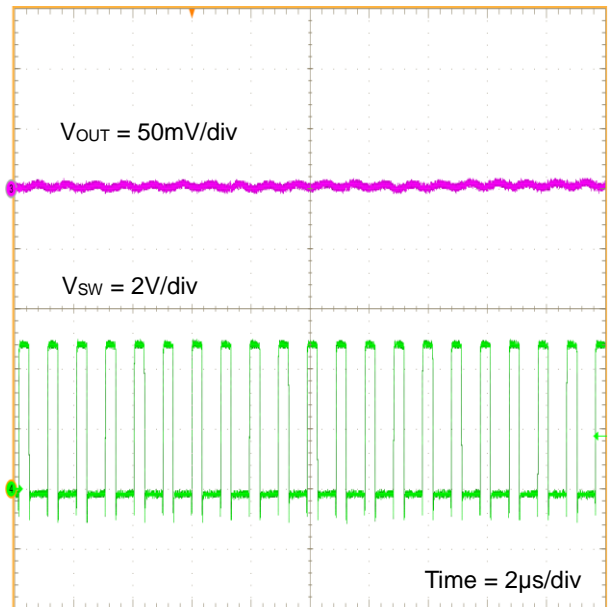(V_{IN} = 5V, V_{OUT} = 1.2V, L = 1.5µH)
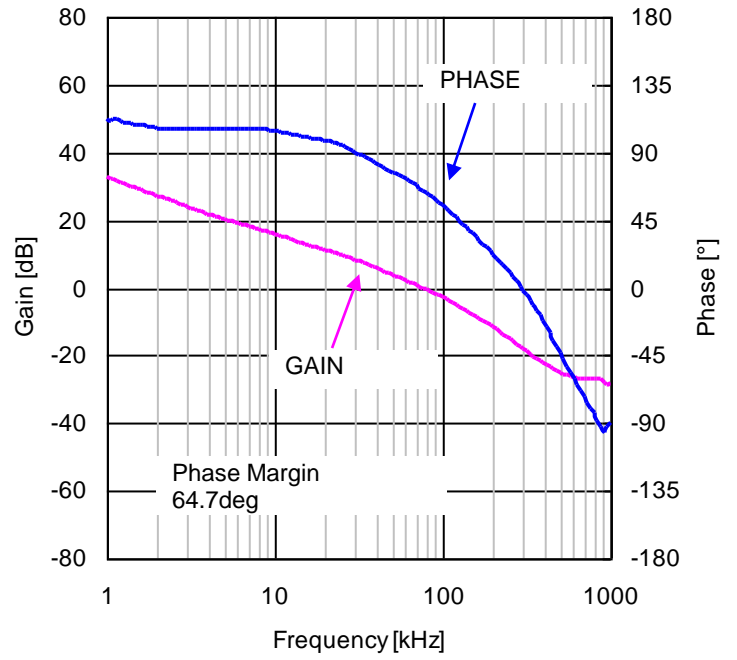

Figure 57. Closed Loop Response I_{OUT} = 1A
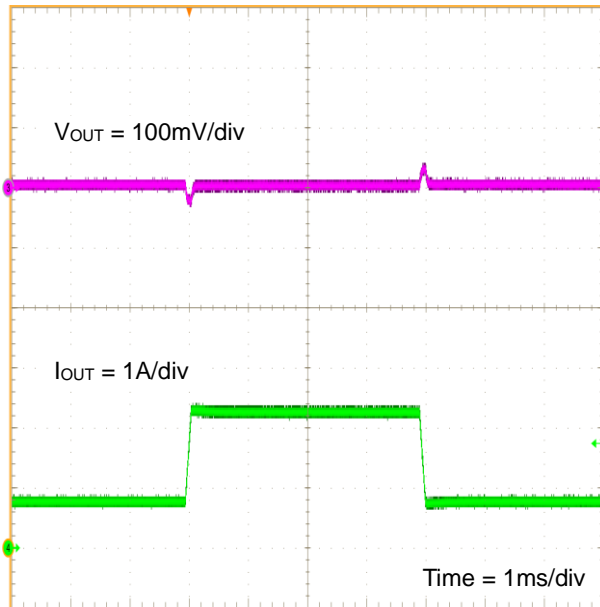(V_{IN} = 5V, V_{OUT} = 1.2V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 58. Load Transient Response
I_{OUT} = 0.75A – 2.25A
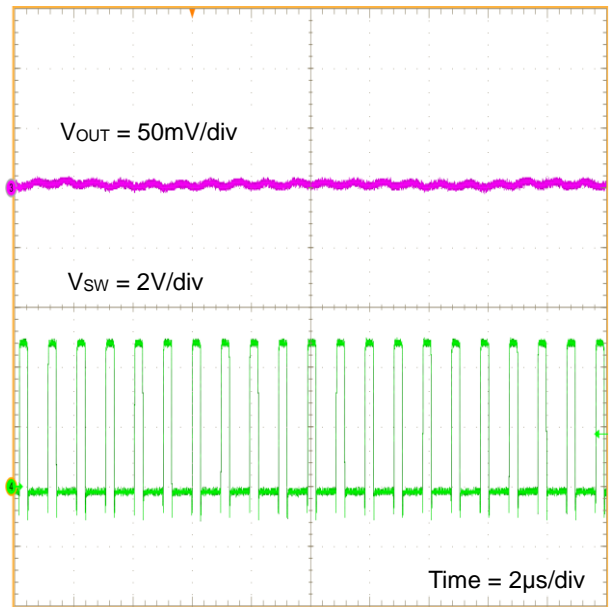(V_{IN} = 5V, V_{OUT} = 1.2V, L = 1.5µH, C_{OUT} = 22µF x 2)

Figure 59. V_{OUT} Ripple I_{OUT} = 3A
(V_{IN} = 5V, V_{OUT} = 1.2V, L = 1.5µH, C_{OUT} = 22µF x 2)

6.   **Selection of Components Externally Connected**

About the application except the recommendation, please contact us.

(1) Output LC Filter Constant
The DC/DC converter requires an LC filter for smoothing the output voltage in order to supply a continuous current to the load. ΔI_L ripple current flowing through the inductor is returned to the BD9A302QWZ for SLLM™ control. It is recommended to use 1.5µH inductor since the feedback current has the best behavior in the specified inductance value.
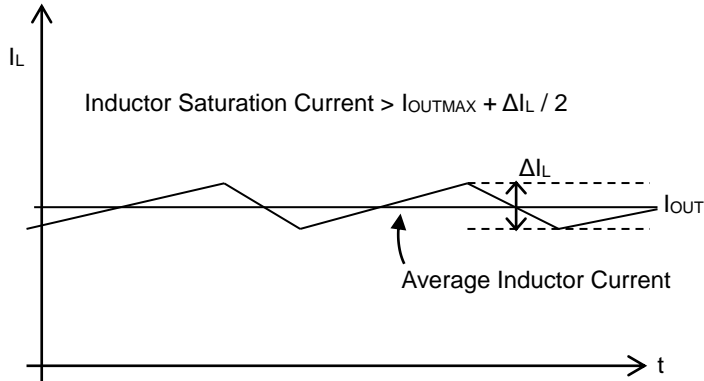
Figure 60. Waveform of Inductor Current
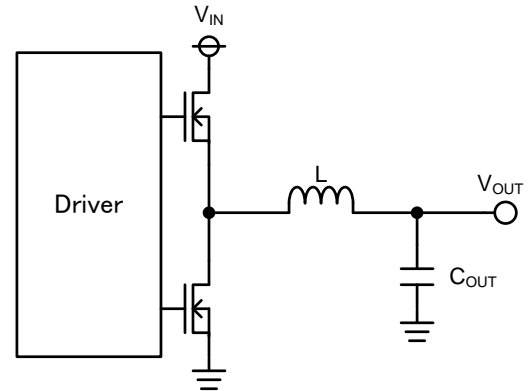
Figure 61. Output LC Filter Circuit

Calculation with V_{IN} = 5V, V_{OUT} = 1.8V, L=1.5µH, and switching frequency f_{OSC} = 1MHz is expressed as below.

Inductor ripple current ΔI_L

$$\Delta I_L = V_{OUT} \times (V_{IN} - V_{OUT}) \times \frac{1}{V_{IN} \times f_{OSC} \times L} = 768\,[\text{mA}]$$

The saturation current of the inductor must be larger than the sum of the maximum output current and one-half (1/2) of the inductor ripple current ΔI_L.

The output capacitor C_{OUT} affects the output ripple voltage characteristics. The output capacitor C_{OUT} must satisfy the required ripple voltage characteristics.

The output ripple voltage can be represented by the following equation.

$$\Delta V_{RPL} = \Delta I_L \times (R_{ESR} + \frac{1}{8 \times C_{OUT} \times f_{OSC}})\,[\text{V}]$$

R_{ESR} is the Equivalent Series Resistance (ESR) of the output capacitor.

Be careful of the total capacitance value, when additional capacitor C_{LOAD} is connected to the output capacitor C_{OUT}. Use maximum additional capacitor C_{LOAD} (Max) condition which satisfies the following method.

Maximum starting inductor ripple current I_{LSTART} < Over Current limit 3.8A (Min)

Maximum starting inductor ripple current I_{LSTART} can be expressed in the following method.

$$I_{LSTART} = Maximum\ starting\ output\ current(I_{OUTMAX}) + Charge\ current\ to\ output\ capacitor(I_{CAP}) + \frac{\Delta I_L}{2}$$

Charge current of the output capacitor I_{CAP} can be expressed in the following method.

$$I_{CAP} = \frac{(C_{OUT} + C_{LOAD}) \times V_{OUT}}{t_{SS}} [A]$$

Calculation with V_{IN}= 5V, V_{OUT}= 3.3V, L= 1.5μH, switching frequency f_{OSC}= 800kHz(Min), output capacitor C_{OUT}= 44μF, Soft Start time t_{SS}= 0.5ms(Min), load current during soft start I_{OSS}= 2A is expressed as below.

$$C_{LOAD}(Max) < \frac{(3.8 - I_{OSS} - \Delta I_L/2) \times t_{SS}}{V_{OUT}} - C_{OUT} = 157.9 \ [μF]$$

(Note) C_{LOAD} has an effect on the stability of the DC/DC converter.
To ensure the stability of the DC/DC converter, make sure that a sufficient phase margin is provided.

(2) Output Voltage Setting
The output voltage value is set by the feedback resistance ratio.
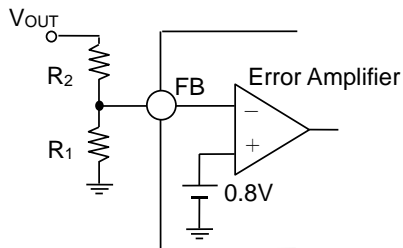
$$V_{OUT} = \frac{R_1 + R_2}{R_1} \times 0.8 \ [V]$$

Figure 62. Feedback Resistors

(3) Phase Compensation Component

A current mode control buck DC/DC converter is a one-pole, one-zero system. One-pole is formed by an error amplifier and load and the one-zero point is added by phase compensation. The phase compensation resistor R_{ITH} determines the crossover frequency f_{CRS} where the total loop gain of the DC/DC converter is 0dB. A high value crossover frequency f_{CRS} provides a good load transient response characteristic but inferior stability. Conversely, a low value crossover frequency f_{CRS} greatly stabilizes the characteristics but the load transient response characteristic is impaired.

(a) Selection of Phase Compensation Resistor R_{ITH}

The Phase Compensation Resistance R_{ITH} can be determined by using the following equation.

$$R_{ITH} = \frac{2\pi \times V_{OUT} \times f_{CRS} \times C_{OUT}}{V_{FB} \times G_{MP} \times G_{MA}} \ [\Omega]$$

Where:
V_{OUT} is the output voltage [V]
f_{CRS} is the crossover frequency [Hz]
C_{OUT} is the output capacitance [F]
V_{FB} is the feedback reference voltage (0.8V (Typ))
G_{MP} is the current sense gain (13A/V (Typ))
G_{MA} is the error amplifier transconductance (260µA/V (Typ))

(b) Selection of Phase Compensation Capacitance C_{ITH}

For stable operation of the DC/DC converter, zero for compensation cancels the phase delay due to the pole formed by the load.

The phase compensation capacitance C_{ITH} can be determined by using the following equation.

$$C_{ITH} = \frac{C_{OUT} \times V_{OUT}}{R_{ITH} \times I_{OUT}} \ [F]$$

(c) Loop Stability

To ensure the stability of the DC/DC converter, make sure that a sufficient phase margin is provided. A phase margin of at least 45º in the worst conditions is recommended.
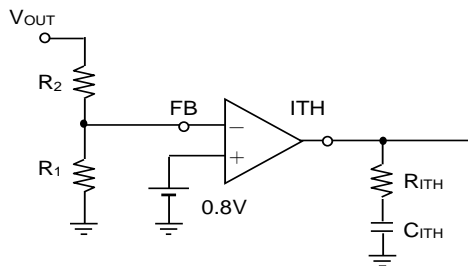
Figure 63. Phase Compensation Circuit
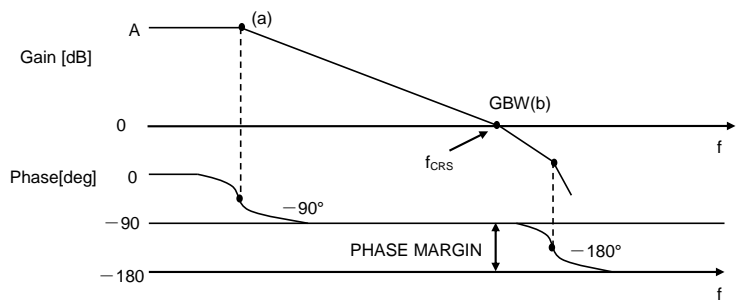
Figure 64. Bode Plot

7. PCB Layout Design

Figure 65 shows a buck DC/DC converter with a large pulsing current flowing into two loops. The first loop is the current flows to the converter when the high-side FET is turned on. The flow starts from the input capacitor C_{IN}, runs through the FET, inductor L and the output capacitor C_{OUT}, back to GND of C_{IN} via GND of C_{OUT}. The second loop is the current flows when the low-side FET is turned on. The flow starts from the low-side FET, runs through the inductor L and output capacitor C_{OUT}, back to GND of the low-side FET via GND of C_{OUT}. Route these two loops as thick and as short as possible to reduce noise for improved efficiency. It is recommended to connect the input and output capacitors directly to the GND plane. The PCB layout has a great influence on the DC/DC converter in terms of the overall heat generation, noise and efficiency characteristics.
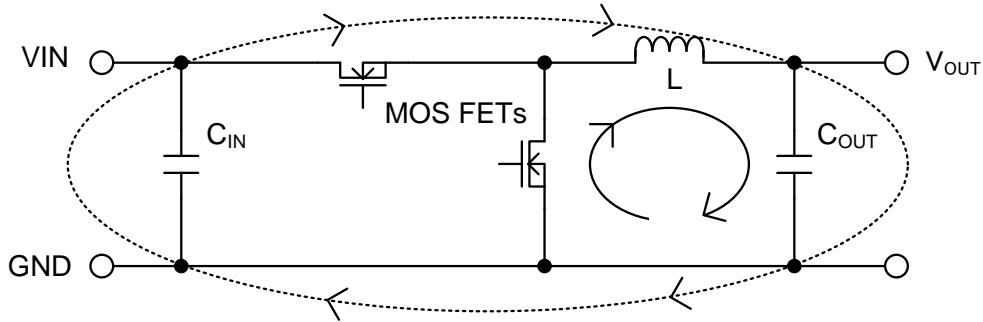
Figure 65. Current Loop of Buck DC/DC Converter

Accordingly, design the PCB layout considering the following points:

(1) Connect an input capacitor as close as possible to the IC VIN terminal and GND terminal on the same plane as the IC.
(2) If there is any unused area on the PCB, provide a copper foil plane for the GND node to assist heat dissipation from the IC and the surrounding components.
(3) Switching nodes such as SW are susceptible to noise due to AC coupling with the other nodes. Route the inductor pattern as thick and as short as possible.
(4) Provide lines connected to FB and ITH terminal with considerable distance from the SW nodes.
(5) Place the output capacitor away from the input capacitor to avoid the propagation of harmonic noise from the input.
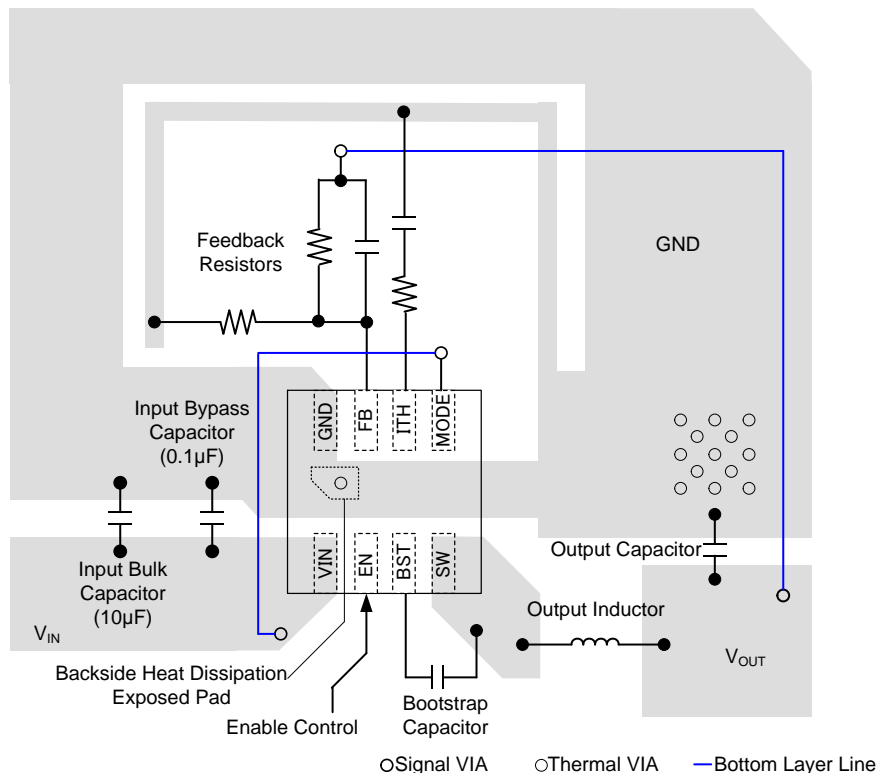
Figure 66. PCB Layout (MODE = H)

I/O Equivalence Circuits
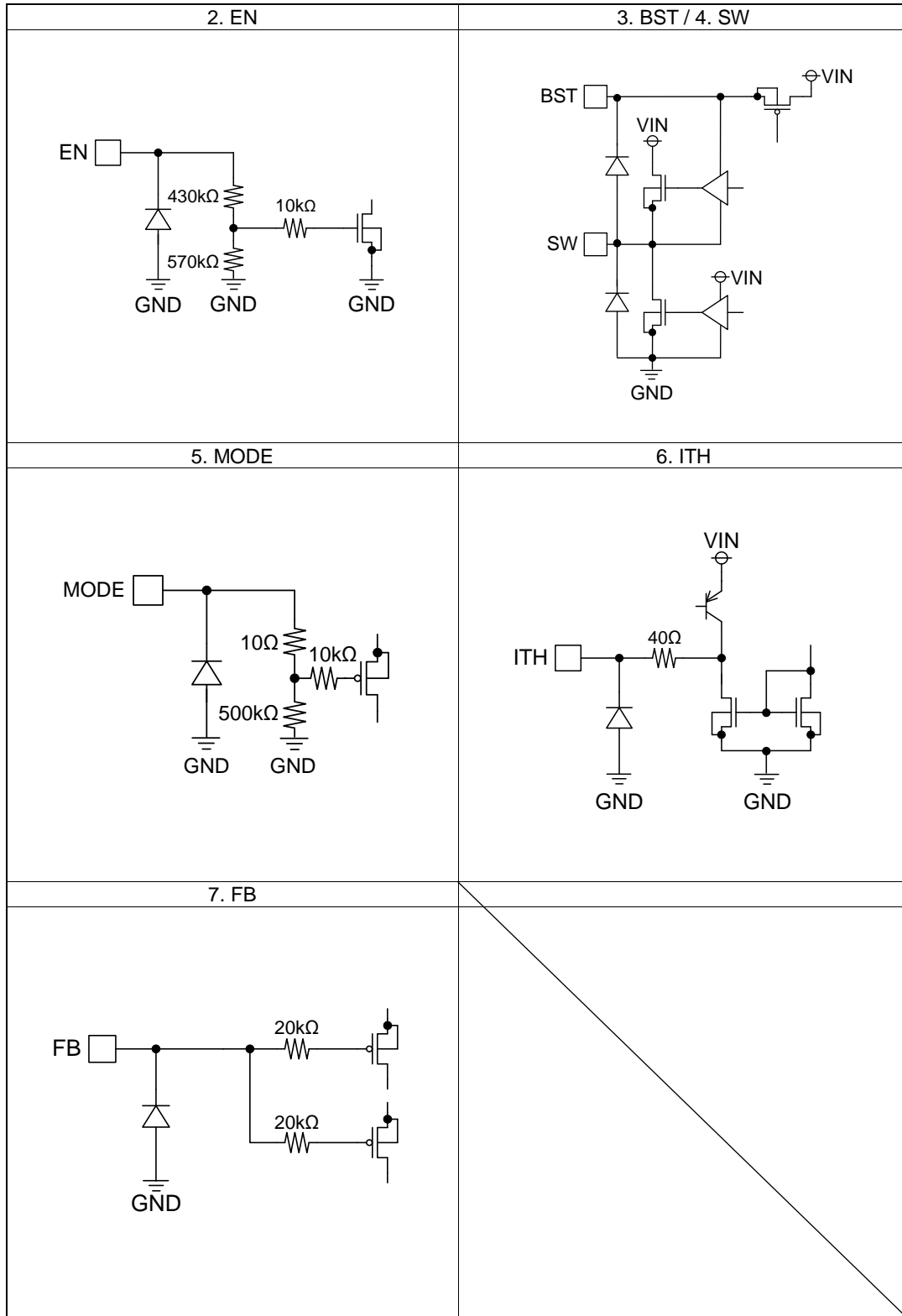
Operational Notes

1. **Reverse Connection of Power Supply**
   Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. **Power Supply Lines**
   Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. **Ground Voltage**
   Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition. However, pins that drive inductive loads (e.g. motor driver outputs, DC-DC converter outputs) may inevitably go below ground due to back EMF or electromotive force. In such cases, the user should make sure that such voltages going below ground will not cause the IC and the system to malfunction by examining carefully all relevant factors and conditions such as motor characteristics, supply voltage, operating frequency and PCB wiring to name a few.

4. **Ground Wiring Pattern**
   When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. **Thermal Consideration**
   Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

6. **Recommended Operating Conditions**
   These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. **Inrush Current**
   When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. **Operation Under Strong Electromagnetic Field**
   Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. **Testing on Application Boards**
   When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. **Inter-pin Short and Mounting Errors**
    Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. **Unused Input Terminals**
    Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

12. Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.
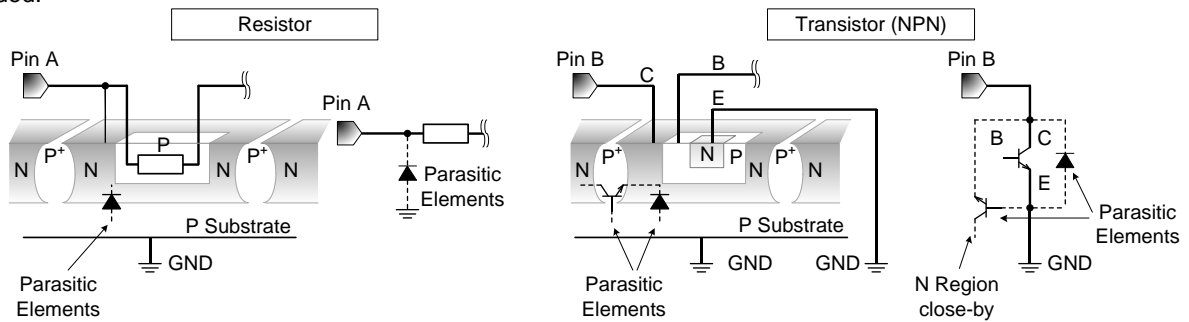

Figure 67. Example of Monolithic IC Structure

13. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and the maximum junction temperature rating are all within the Area of Safe Operation (ASO).

15. Thermal Shutdown Circuit (TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

16. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

17. Disturbance Light

In a device where a portion of silicon is exposed to light such as in a WL-CSP, IC characteristics may be affected due to photoelectric effect. For this reason, it is recommended to come up with countermeasures that will prevent the chip from being exposed to light.

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TSZ22111 • 15 • 001
33/36
TSZ02201-0F3F0AJ00100-1-2
14.Mar.2017 Rev.001

Ordering Information

| B | D | 9 | A | 3 | 0 | 2 | Q | W | Z | - | E 2 |

Part Number

Package
UMMP008AZ020

Packaging and forming specification
E2: Embossed tape and reel

Marking Diagram

UMMP008AZ020 (TOP VIEW)

D 9 A — Part Number Marking

3 0 2

LOT Number

1PIN MARK

Physical Dimension, Tape and Reel Information

Package Name	UMMP008AZ020

2.0±0.1

2.0±0.1

0.4 MAX

/PIN MARK

Ⓢ

⬜ 0.08 Ⓢ

0.35±0.1

0.40±0.1

0.2 +0.05 −0.04

0.4

C0.12

0.36±0.1

0.18

0.63±0.1

0.68±0.1

0.4

(UNIT:mm)

PKG:UMMP008AZ020

< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	4000pcs
Direction of feed	E2
	The direction is the pin 1 of product is at the upper left
	when you hold reel on the left hand and you pull out the tape on the right hand

1234   1234   1234   1234   1234   1234

Reel   Pin 1   Direction of feed

Revision History

Date	Revision	Changes
14.Mar.2017	001	New Release

Notice

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(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
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    - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

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    - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
    - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
    - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
    - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
    - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
    - [f] Sealing or coating our Products with resin or other coating materials
    - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
    - [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
   - [b] the temperature or humidity exceeds those recommended by ROHM
   - [c] the Products are exposed to direct sunshine or condensation
   - [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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